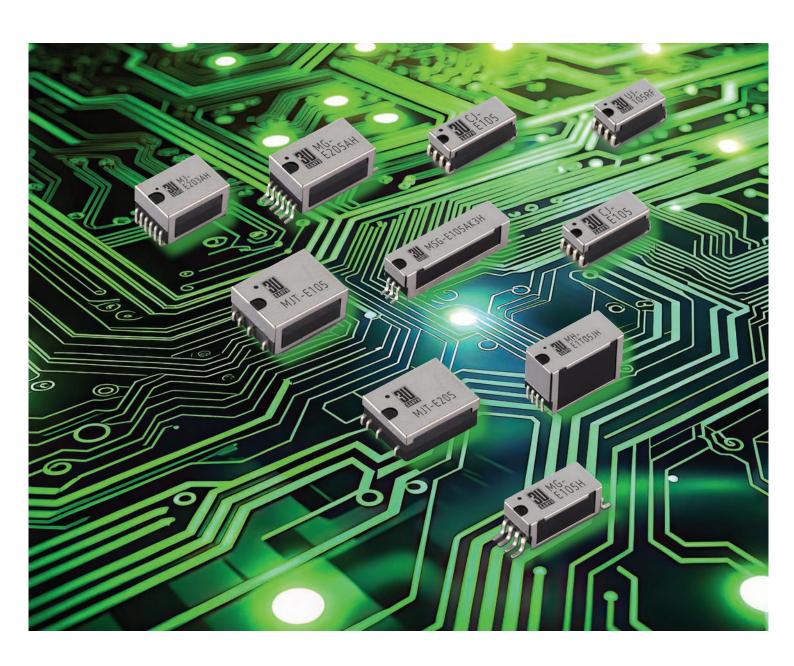
# Surface Mount Reed Relays

*Product Line Brochure* 2025







# **Customer-Centric T&M Innovation: Standex Electronics Acquires Sanyu Switch**

On Feb. 20, 2024, Standex acquired Sanyu Switch Co., Ltd., a Japanese company specializing in reed relays for automated test equipment (ATE) and high-frequency applications. This partnership brings together the strengths of both companies, further enhancing Standex's capabilities.

The acquisition of Sanyu Switch by Standex Electronics brings several benefits to our customers:

- **Enhanced Product Performance:** Efficient, reliable products with improved miniaturization and high-frequency capabilities.
- **Broader Solutions:** Wider range of advanced ATE and high-frequency applications.
- **Customization:** Tailored solutions to meet specific needs.
- Innovation: Cutting-edge technology and ongoing advancements.

Overall, customers can expect higher quality, more reliable, and innovative solutions from Standex Electronics.

Standex Electronics is a trusted and innovative leader in the T&M market. Their dedication to customer satisfaction, global presence, engineering expertise, and ongoing innovation enables them to deliver high-quality, reliable, and customized reed relay solutions tailored to the specific needs of various T&M applications.

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# UJ 1A J-Lead: Ultra-compact, High-frequency Relay



This product was designed to meet the high-density needs in industries such as semiconductor automatic testers and communication measuring instruments. Compared to our CJ 1A high-frequency series, the mount area is reduced by 10%. In addition, these can support frequencies from DC to 8.0GHz, and are one of our products positioned to meet all variety of needs.

#### Characteristics

- Mount area: 7.95mm x 4.67mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{12}\Omega$ 

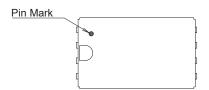
- Frequencies: DC to 8.0GHz (insertion loss: -4dB typ)

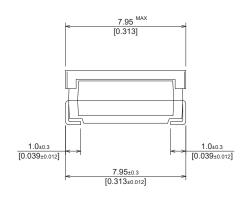


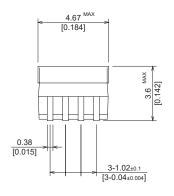
UJ 1A S	eries		UJ-103RF	=		UJ-105	SRF		
Contact Conf	igurations			1 Fo	rm A				1
		•	Coil Spe	ecifications					•
Parameters	Conditions	Min	Nom	Max	Min	Non	ı	Max	Units
Coil Voltage			3.3			5.0			VDC
Coil Resistance	±10% @20°C		90			150	)		Ω
Must Operate	@20℃			2.8				3.75	VDC
Must Release	@20℃	0.5			0.7				VDC
	•	Contac	t Ratings / F	Product Specifi	ications		,		•
Test Parar	meters		Test C	Conditions		Min	Nom	Max	Units
Switching Voltage		DC/Peak A0	C resistance					100	V
Switching Current		DC/Peak A0	C resistance					0.2	Α
Carry Current		DC/Peak A0	C resistance	(@30℃)				0.2	Α
Contact Rating		DC/Peak A0	C resistance					3	W
Life Expectancy		at 1V 10mA				300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Initial C	perete Volta	age				200	mΩ
Contact Resistance	Stability	Max Initial C	perete Volta	age				5	mΩ
Insulation Resistance	Э	Between Co	ntacts			10 <sup>12</sup>			Ω
		Contacts to	Shield			10 <sup>12</sup>			Ω
		Contacts to	Coil			10 <sup>12</sup>			Ω
		Shield to Co	oil			10 <sup>12</sup>			Ω
		(at 100V 2	0°C 65%)						
Dielectric Strength		Between Co	ntacts			150			VDC
(Static)		Contacts to	Shield			500			VDC
		Contacts to	Coil			500			VDC
		Shield to Co	oil			500			VDC
Operate Time		at Nominal (	Coil Voltage					0.25	msec
(Including Bounce)		100Hz Squ	are Wave						
Release Time		Diode Supp	ression					0.05	msec
Measure	ment Reference	Condition			Enviro	nmental	Ratings		•
Temp	: 1	5°C to 35°C	Op	perate temp	: -20°C	to +80°C			
Humidity	: 2	25% to 75%RI	H Ste	orage temp	: -40℃	to +85℃			
Atmospheric Pressui	re : 8	360 to 1060hp		oration	: 20G's	to 2000H	łz		
		Sh	nock	: 50G's					
			Pr	Processing Temp : 260°C max for 60sec. dwell time.					

<sup>★</sup> See p 27 for S-parameters and eye diagram.

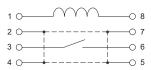
 $<sup>\</sup>bigstar$  For reel packaged version, see p 43.

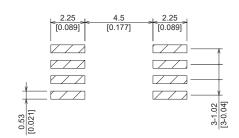












# CJ 1A J-Lead: Ultra-compact, High-frequency SMT Relay



This product was developed to improve upon the frequency characteristics of DC to 4.0GHz and the 1.6Gbps transmission in our existing CJ series. Frequency characteristics were improved to DC-6.0GHz with the ability to reliably transmit signals at 3.2Gbps.

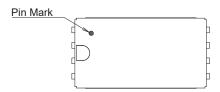
#### Characteristics

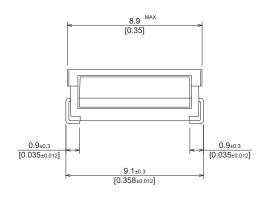
- Mount area: 9.1mm x 4.67mm
- Electrical lifespan: 300 million (@ 1V 10mA)
- Insulation resistance:  $>10^{11}\Omega$
- Frequencies: DC to 6.0GHz (insertion loss: -1dB typ)

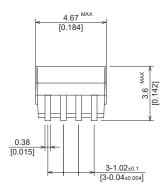


CJ 1A S	eries		CJ-E103	RF		CJ-E10	5RF		
Contact Conf	igurations	†		1 Fo	rm A				1
		•	Coil Sp	pecifications					•
Parameters	Conditions	Min	Nom	Max	Min	Non	ı	Max	Units
Coil Voltage			3.3			5.0			VDC
Coil Resistance	±10% @20°C		90			150	)		Ω
Must Operate	@20℃			2.8				3.75	VDC
Must Release	@20℃	0.5			0.7				VDC
		Contac	t Ratings /	Product Specif	ications				
Test Parar	meters		Test	Conditions		Min	Nom	Max	Units
Switching Voltage		DC/Peak AC	C resistanc	e				100	V
Switching Current		DC/Peak AC	C resistanc	e				0.5	Α
Carry Current		C resistanc					1.0	Α	
Contact Rating		DC/Peak AC	C resistanc	e				10	W
Life Expectancy		at 1V 10mA				300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Initial C	perete Vol	ltage				150	mΩ
Contact Resistance S	Stability	Max Initial C	perete Vo	ltage				5	mΩ
Insulation Resistance	Э	Between Co	ntacts			10 <sup>11</sup>			Ω
		Contacts to	Shield			10 <sup>11</sup>			Ω
		Contacts to	Coil			10 <sup>11</sup>			Ω
		Shield to Co	il			10 <sup>11</sup>			Ω
		(at 100V 20	0°C 65%)						
Dielectric Strength		Between Co	ntacts			200			VDC
(Static)		Contacts to	Shield			250			VDC
		Contacts to	Coil			250			VDC
		Shield to Co	il			250			VDC
Operate Time		at Nominal (	Coil Voltage	е				0.3	msec
(Including Bounce)		100Hz Squ	are Wave						
Release Time		Diode Suppi	ression					0.05	msec
	ment Reference	Condition			Enviro	nmental	Ratings		
Temp	: 1	5°C to 35°C	C	perate temp	: -20°C 1	to +80°C			
Humidity	: 2	25% to 75%RF		Storage temp	: -40℃ 1	to +85℃			
Atmospheric Pressur	re : 8	860 to 1060hp	a V	ibration/	: 20G's	to 2000F	łz		
		_	Shock	: 50G's					
			F	rocessing Tem	p : 260°C	max for (	60sec. c	lwell time	

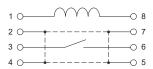
- ★ See p 28 for S-parameters and eye diagram.
- ★ For reel packaged version, see p 43.

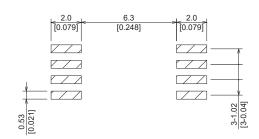












# MG 1A Gull Wing: Compact, High-frequency SMT Relay



This product was developed to improve upon the frequency characteristics of DC to 4.0GHz and the 1.6Gbps transmission in our existing MJ series. The MG/MJ series package was kept completely the same while frequency was improved to DC to 6.0GHz with reliable transmission at 3.2Gbps.

#### Characteristics

- Mount area: 12.7mm x 4.67mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{12}\Omega$ 

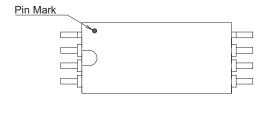
- Frequencies: DC to 6.0GHz (insertion loss: -3dB typ)

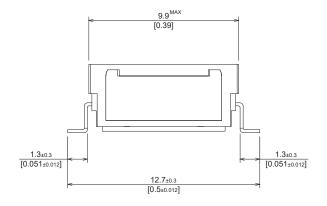


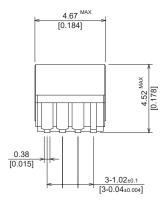
MG 1A S	Series		MG-E105H	H-64				
Contact Conf	igurations		1 Form	A				
	9	Coil S	Specifications					<u> </u>
Parameters	Conditions	Min	Nom			Max		Units
Coil Voltage			5.0					VDC
Coil Resistance	±10% @20°C		200					Ω
Must Operate	@20℃					3.75		VDC
Must Release	@20℃	0.7						VDC
	•	Contact Ratings	/ Product Specificat	ions				
Test Para	meters	Tes	st Conditions		Min	Nom	Max	Units
Switching Voltage		DC/Peak AC resistar	nce				100	V
Switching Current		DC/Peak AC resistar	nce				0.5	Α
Carry Current		DC/Peak AC resistar	nce(@30℃)				1.0	Α
Contact Rating		DC/Peak AC resistar	nce				10	W
Life Expectancy		at 1V 10mA			300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Initial Operete V	'oltage				150	mΩ
Contact Resistance	Stability	Max Initial Operete V	'oltage				5	mΩ
Insulation Resistance	е	Between Contacts			10 <sup>12</sup>			Ω
		Contacts to Shield			10 <sup>12</sup>			Ω
		Contacts to Coil			10 <sup>12</sup>			Ω
		Shield to Coil			10 <sup>12</sup>			Ω
		(at 100V 20°C 65%)	)					
Dielectric Strength		Between Contacts			200			VDC
(Static)		Contacts to Shield			250			VDC
		Contacts to Coil			250			VDC
		Shield to Coil			250			VDC
Operate Time		at Nominal Coil Volta	ige				0.3	msec
(Including Bounce)		100Hz Square Wav	e					
Release Time		Diode Suppression					0.05	msec
Measure	ment Reference	Condition		Enviror	nmental	Ratings		•
Temp	: 1	5°C to 35°C	Operate temp : -20°C to +80°C					
Humidity	: 2	25% to 75%RH	Storage temp : -40°C to +85°C					
Atmospheric Pressu	re : 8	360 to 1060hpa	Vibration : 20G's to 2000Hz					
			Shock	: 50G's				
	001.0		Processing Temp : 260°C max for 60sec. dwell time.					

<sup>★</sup> See p 29 for S-parameters and eye diagram.

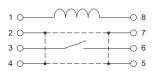
 $<sup>\</sup>bigstar$  For reel packaged version, see p 43.

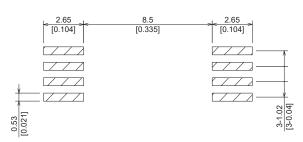












# CJ 1A J-Lead: Ultra-compact SMT Relay



This product was developed as an even smaller version of our MJ series. This series offers a 30% reduction in mount area compared to our MJ series. While being compact, it still maintains SMT industry-standard properties and supports frequencies from DC to 4.0GHz.

#### Characteristics

- Mount area: 9.1mm x 3.81mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

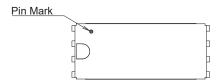
- Frequencies: DC to 4.0GHz (insertion loss: -3dB typ)

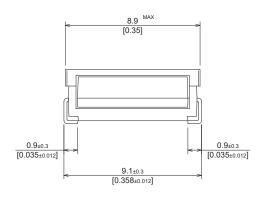


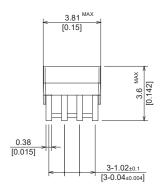
CJ 1A S	eries		CJ-E103	}		CJ-E1	05			
Contact Conf	igurations			1 Fo	rm A				1	
		•	Coil Spe	ecifications					•	
Parameters	Conditions	Min	Nom	Max	Min	Non	ı	Max	Units	
Coil Voltage			3.3			5.0			VDC	
Coil Resistance	±10% @20°C		100			200	)		Ω	
Must Operate	@20℃			2.8				3.75	VDC	
Must Release	@20℃	0.5			0.7				VDC	
	-	Contac	t Ratings /	Product Specif	ications					
Test Parar	meters		Test C	Conditions		Min	Nom	Max	Units	
Switching Voltage		DC/Peak A0	C resistance	)				100	V	
Switching Current		DC/Peak A0	C resistance	•				0.5	Α	
Carry Current		DC/Peak A0	C resistance	(@30℃)				1.0	Α	
Contact Rating		DC/Peak A0	C resistance	<b>;</b>				10	W	
Life Expectancy		at 1V 10mA				300			x10 <sup>6</sup> Cycle	
Contact Resistance		Max Initial C	perete Volt	age				150	mΩ	
Contact Resistance	Stability	Max Initial C	perete Volt	age				5	mΩ	
Insulation Resistance	Э	Between Co	ntacts			10 <sup>11</sup>			Ω	
		Contacts to	Shield			10 <sup>11</sup>			Ω	
		Contacts to	Coil			10 <sup>11</sup>			Ω	
		Shield to Co	oil			10 <sup>11</sup>			Ω	
		(at 100V 2	0°C 65%)							
Dielectric Strength		Between Co	ntacts			200			VDC	
(Static)		Contacts to	Shield			250			VDC	
		Contacts to	Coil			250			VDC	
		Shield to Co	oil			250			VDC	
Operate Time		at Nominal (	Coil Voltage					0.3	msec	
(Including Bounce)		100Hz Squ	are Wave							
Release Time		Diode Supp	ression					0.05	msec	
Measure	ment Reference	Condition			Enviro	nmental l	Ratings			
Temp	: 1	5°C to 35°C	O	perate temp	: -20°C	to +80°C	•			
Humidity	: 2	25% to 75%RI		orage temp	: -40℃	to +85℃				
Atmospheric Pressu	re : 8	360 to 1060hp	a Vi	bration	: 20G's	to 2000H	łz			
		St	nock	: 50G's						
			Pr	Processing Temp : 260°C max for 60sec. dwell time.						

<sup>★</sup> See p 30 for S-parameters and eye diagram.

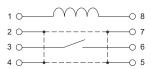
 $\bigstar$  For reel packaged version, see p 43.

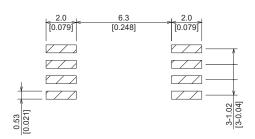












# MG 1A Gull Wing: Compact SMT Relay



This product was developed as an even smaller version of our MSG series. This series offers a 38% reduction in mount area compared to our MSG series. Since announcing this product, it has been a long-term bestseller as the industry standard for relays used in semiconductor automatic test equipment (ATE). This relay solves a variety of needs by combining both the properties and reliability required in the ATE industry.

#### Characteristics

- Mount area: 12.7mm x 4.67mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

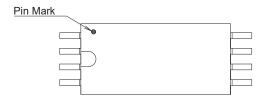
- Frequencies: DC to 4.0GHz (insertion loss: -3dB typ)

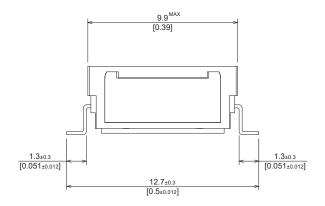


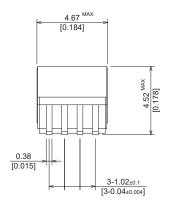
MG 1A S	Series		MG-E105	5H		MG-E1	12H		
Contact Conf	igurations			1 F	orm A				
	<u> </u>		Coil Sp	pecifications					
Parameters	Conditions	Min	Nom	Max	Min	Nom	ı	Max	Units
Coil Voltage			5.0			12.0	)		VDC
Coil Resistance	±10% @20°C		150			500	)		Ω
Must Operate	@20℃			3.75				8.8	VDC
Must Release	@20℃	0.7			1.2				VDC
		Contac	t Ratings /	Product Spec	ifications				
Test Parar	neters		Test	Conditions		Min	Nom	Max	Units
Switching Voltage		DC/Peak A	C resistanc	е				100	V
Switching Current		DC/Peak A	C resistanc	e				0.5	Α
Carry Current		DC/Peak A	C resistanc	e(@30℃)				1.0	Α
Contact Rating		DC/Peak A	C resistanc	e				10	W
Life Expectancy		at 1V 10mA				300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Initial C	Operete Vo	Itage				150	mΩ
Contact Resistance	Stability	Max Initial C	Operete Vo	Itage				5	mΩ
Insulation Resistance	Э	Between Co	ontacts			10 <sup>11</sup>			Ω
		Contacts to	Shield			10 <sup>11</sup>			Ω
		Contacts to	Coil			10 <sup>11</sup>			Ω
		Shield to Co	oil			10 <sup>11</sup>			Ω
		(at 100V 2	0°C 65%)						
Dielectric Strength		Between Co	ontacts			200			VDC
(Static)		Contacts to	Shield			250			VDC
		Contacts to	Coil			250			VDC
		Shield to Co	oil			250			VDC
Operate Time		at Nominal	Coil Voltag	е				0.3	msec
(Including Bounce)		100Hz Squ							
Release Time		Diode Supp	ression					0.05	msec
Measure	ment Reference	Condition			nmental l	Ratings			
Temp	: 1	5°C to 35°C		Operate temp		to +80°C			
Humidity		25% to 75%RI	н [s	Storage temp	: -40℃ 1	to +85℃			
Atmospheric Pressu	re : 8	360 to 1060hp		/ibration		to 2000H	łz		
		5	Shock	: 50G's					
	04 ( 0		F	Processing Ten	np : 260°C	max for 6	60sec. d	well time	

<sup>★</sup> See p 31 for S-parameters and eye diagram.

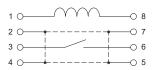
<sup>★</sup> For reel packaged version, see p 43.

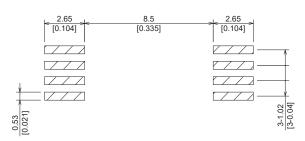












# MJ 1A J-Lead: Compact SMT Relay



This product was developed as an even smaller version of our MSG series. This series offers a 38% reduction in mount area compared to our MSG series. Since announcing this product, it has been a long-term bestseller as the industry standard for relays used in semiconductor automatic test equipment (ATE). This relay solves a variety of needs by combining both the properties and reliability required in the ATE industry.

#### Characteristics

- Mount area: 10.16mm x 4.67mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

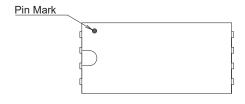
- Frequencies: DC to 4.0GHz (insertion loss: -3dB typ)

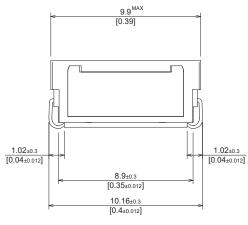


MJ 1A S	Series		MJ-E105H			MJ-E11	12H				
Contact Conf	figurations	1		1 Fo	rm A				1		
		•	Coil Spe	cifications					•		
Parameters	Conditions	Min	Nom	Max	Min	Non	ı	Max	Units		
Coil Voltage			5.0			12.0	)		VDC		
Coil Resistance	±10% @20°C		150			500	)		Ω		
Must Operate	@20℃			3.75				8.8	VDC		
Must Release	@20℃	0.7			1.2				VDC		
		Contac		roduct Specifi	cations						
Test Para	meters		Test C	onditions		Min	Nom	Max	Units		
Switching Voltage		DC/Peak AC	C resistance					100	V		
Switching Current		DC/Peak AC	C resistance					0.5	Α		
Carry Current		DC/Peak AC	c resistance	(@30℃)				1.0	Α		
Contact Rating		DC/Peak AC	C resistance					10	W		
Life Expectancy		at 1V 10mA				300			x10 <sup>6</sup> Cycle		
Contact Resistance			perete Volta					150	mΩ		
Contact Resistance	Stability	Max Initial C	perete Volta	ige				5	mΩ		
Insulation Resistance	е	Between Co	ntacts			10 <sup>11</sup>			Ω		
		Contacts to	Shield			10 <sup>11</sup>			Ω		
		Contacts to	Coil			10 <sup>11</sup>			Ω		
		Shield to Co	il			10 <sup>11</sup>			Ω		
		(at 100V 20	0°C 65%)								
Dielectric Strength		Between Co	ntacts			200			VDC		
(Static)		Contacts to	Shield			250			VDC		
		Contacts to	Coil			250			VDC		
		Shield to Co				250			VDC		
Operate Time		at Nominal (	Coil Voltage					0.3	msec		
(Including Bounce)		100Hz Squ	are Wave								
Release Time		Diode Supp	ression					0.05	msec		
Measure	ment Reference	Condition		Environmental Ratings							
Temp		5°C to 35°C		Operate temp : -20°C to +80°C							
Humidity		25% to 75%RI		Storage temp : -40°C to +85°C							
Atmospheric Pressu	re : 8	860 to 1060hp		ration		to 2000F	lz				
				ock	: 50G's						
			Pro	Processing Temp : 260°C max for 60sec. dwell time.							

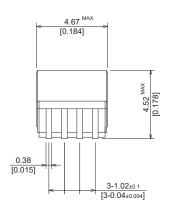
<sup>★</sup> See p 31 for S-parameters and eye diagram.

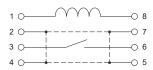
★ For reel packaged version, see p 43.

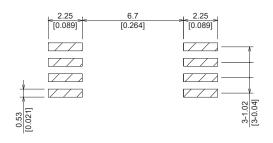












# MSG 1A Gull Wing: High Contact Capacity SMT Relay



This product was developed with the aim of increasing the industry standard maximum contact capacity of 10W to 30W. The maximum contact capacity was increased to 30W, improving the operating switching voltage to 200V, with an electrical lifespan of over 1.5 billion cycles. This resulted in a great improvement in solving load-related needs. In addition to the properties and reliability needed for semiconductor automatic testers, this product is also suitable for DC characteristic testing.

### Characteristics

- Mount area: 20.4mm x 4.5mm

- Electrical lifespan: 1.5 billion (@ 1V 10mA)

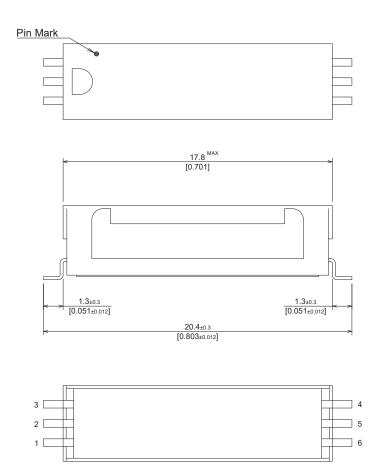
Max switching voltage: 200VDCBreakdown voltage: 300VDC

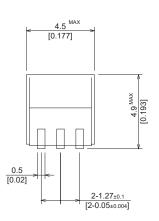


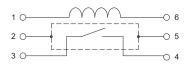
MSG 1A	Series	M	ISG-105 <i>A</i>	K3H	N	1SG-112	AK3H		
Contact Cor	nfigurations			1 F	orm A				
			Coil S	pecifications					•
Parameters	Conditions	Min	Nom	Max	Min	Nom	ı	Max	Units
Coil Voltage			5.0			12.0	)		VDC
Coil Resistance	±10% @20°C		160			600			Ω
Must Operate	@20℃			3.75				8.8	VDC
Must Release	@20℃	0.7			1.2				VDC
	•	Contac	t Ratings	Product Spec	ifications				•
Test Para	ameters		Test	Conditions		Min	Nom	Max	Units
Switching Voltage		DC/Peak A0	C resistand	е				200	V
Switching Current		DC/Peak AC	C resistand	e				0.5	Α
Carry Current		DC/Peak A0	C resistand	e(@30℃)				1.3	Α
Contact Rating		DC/Peak A0	C resistand	ce				30	W
Life Expectancy		at 1V 10mA				1500			x10 <sup>6</sup> Cycle
Contact Resistance	)	Max Initial C	perete Vo	ltage				150	mΩ
Contact Resistance	Stability	Max Initial C	Operete Vo	ltage				5	mΩ
Insulation Resistan	се	Between Co	ontacts		10 <sup>11</sup>			Ω	
		Contacts to	Shield			10 <sup>11</sup>			Ω
		Contacts to	Coil			10 <sup>11</sup>			Ω
		Shield to Co	oil			10 <sup>11</sup>			Ω
		(at 100V 2	0°C 65%)						
Dielectric Strength		Between Co	ntacts			300			VDC
(Static)		Contacts to	Shield			500			VDC
,		Contacts to	Coil			500			VDC
		Shield to Co	oil			500			VDC
Operate Time		at Nominal (	Coil Voltag	е				0.5	msec
(Including Bounce)		100Hz Squ	are Wave						
Release Time		Diode Supp	ression					0.2	msec
Measur	ement Reference	Condition			Enviro	nmental	Ratings		•
Temp	: 1	5°C to 35°C	(	Operate temp	: -20°C	to +80°C			
Humidity	: 2	25% to 75%RI	H	Storage temp	: -40℃	to +85℃			
Atmospheric Press	ure : 8	360 to 1060hp	a \	/ibration	: 20G's	to 2000H	lz		
			5	Shock	: 50G's				
			F	Processing Ter	mp : 260°C	max for 6	60sec. d	well time	

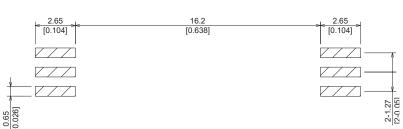
<sup>★</sup> See p 32 for S-parameters and eye diagram.

<sup>★</sup> For reel packaged version, see p 43.









# MG 2A Gull Wing: Compact SMT Relay



This product was developed with the aim of significantly reducing the mount area while maintaining a max contact rating of 10W for a 2-make (2A) relay. Conventional 2-make relays with a max contact capacity of 10W had a mount area of 14mm² or more, but this series reduced the mount area by half. This series is ideal for DC pulse transmission, circuits around ATE pin electronics, and PMU circuits.

#### Characteristics

- Mount area: 12.7mm x 6.7mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

- Frequencies: DC to 4.0GHz (insertion loss: -1dB typ)



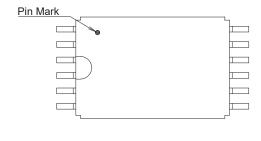
MG 2A S	Series	М	G-E203/	λΗ	М	G-E205 <i>A</i>	λΗ	M	G-E212 <i>A</i>	λΗ	
Contact Conf	igurations	1				2 Form A	7	<u> </u>			
Contact Con	igarations			oil Spe	cificatior						1
Parameters	Conditions	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Coil Voltage			3.3			5.0			12.0		VDC
Coil Resistance	±10% @20°C		70			110			550		Ω
Must Operate	@20℃			2.8			3.75			8.8	VDC
Must Release	@20℃	0.5			0.7			1.2			VDC
	•	Contact Ratings / Product Specifications									
Test Parar	meters		Test Conditions Min Nom								Units
Switching Voltage		istance						100	V		
Switching Current		istance						0.5	Α		
Carry Current		istance	@30℃)					1.0	Α		
Contact Rating		DC/Pea	k AC res	istance						10	W
Life Expectancy		at 1V 10	)mA					300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Init	ial Opere	ete Volta	ge					150	mΩ
Contact Resistance	Stability	Max Init	ial Opere	ete Volta	ge					5	mΩ
Insulation Resistance	Э	Between	n Contac	ts				10 <sup>11</sup>			Ω
		Contact	s to Shie	ld				10 <sup>11</sup>			Ω
		Contact	s to Coil					10 <sup>11</sup>			Ω
		Shield to	Coil					10 <sup>11</sup>			Ω
		(at 100	V 20°C 6	65%)							
Dielectric Strength		Between	n Contac	ts				200			VDC
(Static)			s to Shie	ld				250			VDC
		Contact	s to Coil					250			VDC
		Shield to	Coil					250			VDC
Operate Time			nal Coil \	0						0.5	msec
(Including Bounce)			Square \								
Release Time		on						0.5	msec		
	ment Reference							nmental	Ratings		
Temp		5°C to 35	-		erate tem	•		to +80°C			
Humidity		25% to 75			rage tem	р		to +85℃			
Atmospheric Pressur	re : 8	360 to 106	0hpa		ration			to 2000F	łz		
					ock		: 50G's				
	- 22 24 for C =				cessing	Temp	: 260°C	max for	60sec. dv	vell time	

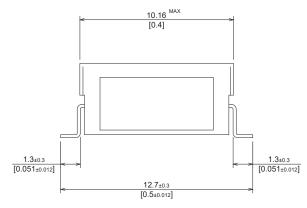
<sup>★</sup> See p 33, 34 for S-parameters and eye diagram.

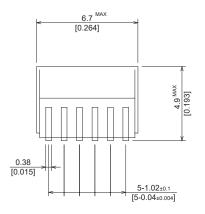
<sup>★</sup> For reel packaged version, see p 43.

### Dimensions < All Dimensions are mm(inch) >

\* Pin mark ( • ) corresponds to the terminal number 1.

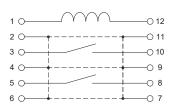


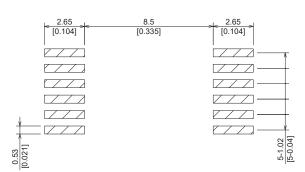






### Schematic <Top View>





# MJ 2A J-Lead: Compact SMT Relay



This product was developed with the aim of significantly reducing the mount area while maintaining a max contact rating of 10W for a 2-make (2A) relay. Conventional 2-make relays with a max contact capacity of 10W had a mount area of 14mm² or more, but this series reduced the mount area by half. This series is ideal for DC pulse transmission, circuits around ATE pin electronics, and PMU circuits.

#### Characteristics

- Mount area: 10.8mm x 6.7mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

- Frequencies: DC to 4.0GHz (insertion loss: -1dB typ)



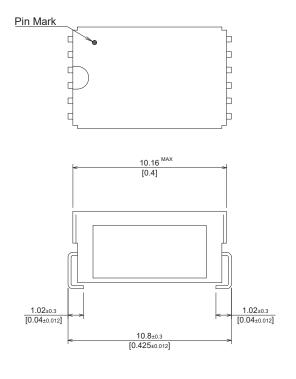
MJ 2A S	MJ 2A Series  Contact Configurations		J-E203A	ιH	MJ-E205AH			N			
Contact Conf	igurations					2 Form A	١	•			1
			C	oil Spec	cification	IS					
Parameters	Conditions	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Coil Voltage			3.3			5.0			12.0		VDC
Coil Resistance	±10% @20°C		70			110			550		Ω
Must Operate	@20℃			2.8			3.75			8.8	VDC
Must Release	@20℃	0.5			0.7			1.2			VDC
		Co	ntact Ra	tings / Pi	oduct Sp	ecification	ons				
Test Parar	meters				nditions			Min	Nom	Max	Units
Switching Voltage			k AC res							100	V
Switching Current		DC/Pea	k AC res	istance						0.5	Α
Carry Current		DC/Pea	k AC res	istance(	@30℃)					1.0	Α
Contact Rating		DC/Pea	k AC res	istance						10	W
Life Expectancy		)mA					300			x10 <sup>6</sup> Cycle	
Contact Resistance			ial Opere							150	mΩ
Contact Resistance	Stability	Max Init	ial Opere	te Volta	ge			10 <sup>11</sup>		5	mΩ
Insulation Resistance	Э		Between Contacts								Ω
		Contact	s to Shie	ld				10 <sup>11</sup>			Ω
		Contact	s to Coil					10 <sup>11</sup>			Ω
		Shield to	o Coil					10 <sup>11</sup>			Ω
		(at 100	V 20°C 6	55%)							
Dielectric Strength		Betweer	n Contac	ts				200			VDC
(Static)		Contact	s to Shie	ld				250			VDC
		Contact	s to Coil					250			VDC
		Shield to	Coil					250			VDC
Operate Time		at Nomi	nal Coil \	/oltage						0.5	msec
(Including Bounce)		100Hz	Square \	Vave							
Release Time			uppressi	on						0.5	msec
	ment Reference	Condition	1				Enviro	nmental	Ratings		
Temp		5°C to 35			erate tem			to +80°C			
Humidity		5% to 75°		Storage temp : -40℃ to +85℃							
Atmospheric Pressure : 860 to 1060hpa					ration			to 2000F	łz		
				Sho	ck		: 50G's				
			Processing Temp : 260°C max for 60sec. dwell time.								

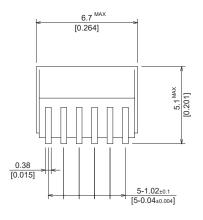
<sup>★</sup> See p 33, 34 for S-parameters and eye diagram.

<sup>★</sup> For reel packaged version, see p 43.

### Dimensions < All Dimensions are mm(inch) >

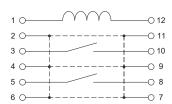
\* Pin mark ( • ) corresponds to the terminal number 1.

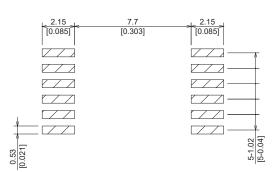






# Schematic <Top View>





# MH 1A1B J-Lead: Vertical SMT Relay



This product was developed to miniaturize our long-life, high-reliability MJT series. The contact configuration is single transfer (1A+1B), achieving 34% reduction in mount area compared to the MJT series. Among our SMT single transfer products, it is the smallest and most suitable for high-density mounting.

#### Characteristics

- Mount area: 10.16mm x 5.08mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 



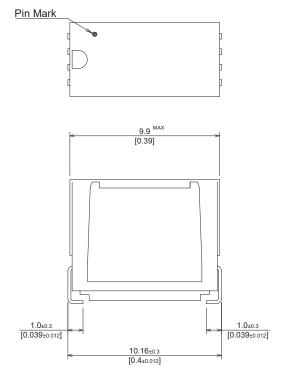
MH 1A1B	Series	MH	I-E1T03	JH	MH	1-E1T05	5JH	MH	1-E1T12	2JH	
Contact Conf	igurations				1 Fc	rm C (A	+ B)				
			C	oil Spe	cificatior	ıs					
Parameters	Conditions	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Coil Voltage			3.3	3.6		5.0	5.5		12.0	13.2	VDC
Coil Resistance	±10% @20°C		70			110			550		Ω
Must Operate	@20℃			2.8			3.75			8.8	VDC
Must Release	@20℃	0.5			0.7			1.2			VDC
		Co	ntact Ra	tings / F	roduct Sp	oecificati	ons				
Test Parar	neters			Test C	onditions			Min	Nom	Max	Units
Switching Voltage		DC/Pea	k AC res	istance						100	V
Switching Current		DC/Pea	k AC res	istance						0.5	Α
Carry Current		istance	@30℃)					1.0	Α		
Contact Rating		istance						10	W		
Life Expectancy		at 1V 10	)mA					300			x10 <sup>6</sup> Cycle
Contact Resistance		Max Init	ial Opere	ete Volta	ge					150	mΩ
Contact Resistance	Stability	Max Init	ial Opere	ete Volta	ge					5	mΩ
Insulation Resistance	Э	Between	n Contac	ts				10 <sup>11</sup>			Ω
		Contact	s to Shie	ld				10 <sup>11</sup>			Ω
		Contact	s to Coil					10 <sup>11</sup>			Ω
		Shield to	Coil					10 <sup>11</sup>			Ω
		(at 100	V 20°C 6	55%)							
Dielectric Strength		Between	n Contac	ts				200			VDC
(Static)		Contact	s to Shie	ld				500			VDC
		Contact	s to Coil					500			VDC
		Shield to	Coil					500			VDC
Operate Time		at Nomi	nal Coil \	/oltage						0.5	msec
(Including Bounce)		100Hz	Square \	Vave							
Release Time			uppressi	on						0.5	msec
	ment Reference	Condition	1				Enviro	nmental	Ratings		
Temp	: 1	5°C to 35	°C		erate tem			o +60°C			
Humidity	: 2	25% to 75	%RH	Storage temp : -40℃ to +85℃							
Atmospheric Pressur	re : 8	860 to 106	0hpa	Vik	ration		: 20G's	to 2000F	łz		
	Sh	ock		: 50G's							
				Pro	cessing	Temp	: 260°C	max for (	60sec. dv	vell time	

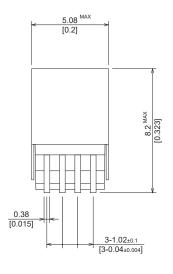
<sup>★</sup> See p 35, 36 for S-parameters and eye diagram.

<sup>★</sup> For reel packaged version, see p 43.

### Dimensions < All Dimensions are mm(inch) >

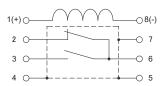
\* Pin mark ( • ) corresponds to the terminal number 1.

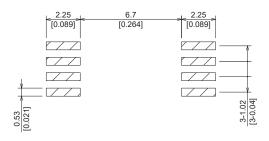






## Schematic <Top View>





<sup>\*</sup> Coil polarities, (+) and (-).

# MGT 1A1B Gull Wing: Compact SMT Relay



This product uses two make switches to create a transfer switch (1A+1B), thereby improving lifespan and reliability. Using make contact points extends the lifespan and achieving high reliability. This product is therefore highly valued in the semiconductor tester and measurement equipment industries.

### Characteristics

- Mount area: 12.7mm x 7.62mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

- Frequencies: DC to 2.5GHz (insertion loss: -1dB typ)



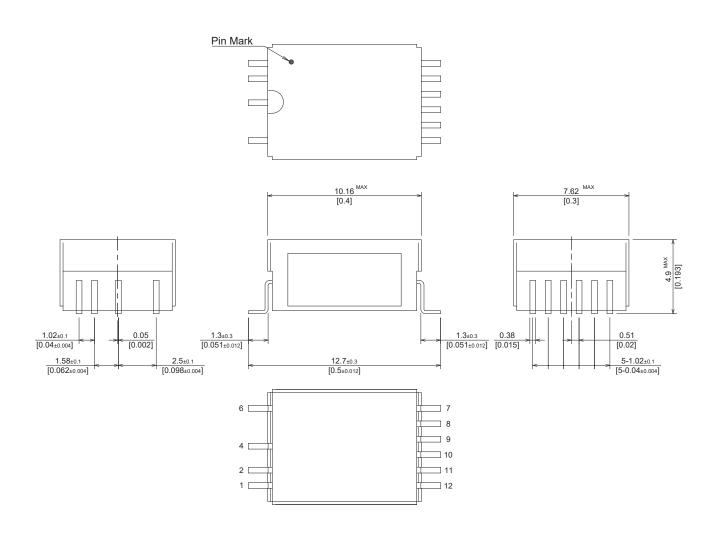
MGT 1A1B	Series	М	GT-E103	ЗН	М	GT-E105	5H	М	GT-E112	2H	
Contact Conf	igurations				1 Fc	rm C (A	+ B)				1
			C	oil Spe	cification	ıs					
Parameters	Conditions	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Coil Voltage			3.3	3.6		5.0	5.5		12.0	13.2	VDC
Coil Resistance	±10% @20°C		70			110			550		Ω
Must Operate	@20℃			2.8			3.75			8.8	VDC
Must Release	@20℃	0.5			0.7			1.2			VDC
		Co	ntact Ra	tings / P	roduct Sp	ecification	ons				
Test Parar	meters				onditions			Min	Nom	Max	Units
Switching Voltage			k AC res							100	V
Switching Current		DC/Pea	k AC res	istance						0.5	Α
Carry Current		DC/Pea	k AC res	istance(	@30℃)					1.0	Α
Contact Rating	nct Rating DC/Peak AC resistance									10	W
Life Expectancy		at 1V 10mA 300									x10 <sup>6</sup> Cycle
Contact Resistance		Max Initial Operete Voltage									mΩ
Contact Resistance S	Stability	Max Init	ial Opere	ete Volta	ge					5	mΩ
Insulation Resistance	Э		n Contac					10 <sup>11</sup>			Ω
		Contact	s to Shie	ld				10 <sup>11</sup>			Ω
			s to Coil					10 <sup>11</sup>			Ω
		Shield to	o Coil					10 <sup>11</sup>			Ω
		`	V 20°C 6	,							
Dielectric Strength		Between	n Contac	ts				200			VDC
(Static)		Contact	s to Shie	ld				250			VDC
		Contact	s to Coil					250			VDC
		Shield to						250			VDC
Operate Time		at Nomi	nal Coil \	/oltage						0.5	msec
(Including Bounce)			Square \								
Release Time			uppressi	on						0.5	msec
	ment Reference							nmental	Ratings		
Temp		5°C to 35			erate tem			to +80°C			
Humidity		5% to 75			rage tem	р		to +85℃			
Atmospheric Pressur	re : 8	60 to 106	0hpa		ration			to 2000F	lz		
				Sho			: 50G's				
			Processing Temp : 260°C max for 60sec. dwell time.								

<sup>★</sup> See p 37, 38 for S-parameters and eye diagram.

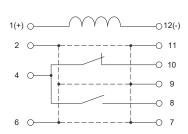
<sup>★</sup> For reel packaged version, see p 43.

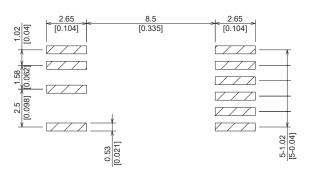
### Dimensions < All Dimensions are mm(inch) >

\* Pin mark ( • ) corresponds to the terminal number 1.



### Schematic <Top View>





<sup>\*</sup> Coil polarities, (+) and (-).

# MJT 1A1B J-Lead: Compact SMT Relay



This product uses two make switches to create a transfer switch (1A+1B), thereby improving lifespan and reliability. Using make contact points extends the lifespan and achieving high reliability. This product is therefore highly valued in the semiconductor tester and measurement equipment industries.

#### Characteristics

- Mount area: 10.8mm x 7.62mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

- Frequencies: DC to 2.5GHz (insertion loss: -1dB typ)



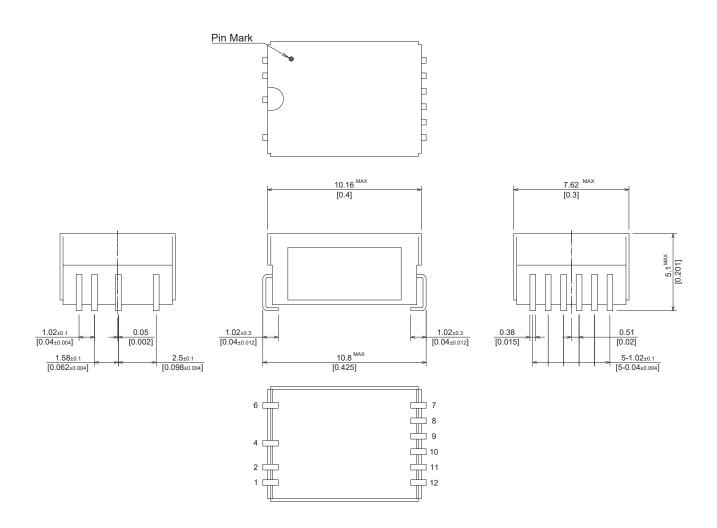
Contact Configurations  Parameters Conditions	I	MJT-E103H			MJT-E105H			IJT-E112				
		1 Form C (A + B)							1			
	Coil Specifications											
-!  \ / -   (	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units		
oil Voltage		3.3	3.6		5.0	5.5		12.0	13.2	VDC		
coil Resistance ±10% @20°C		70			110			550		Ω		
lust Operate @20℃			2.8			3.75			8.8	VDC		
lust Release @20℃	0.5			0.7			1.2			VDC		
	Co	ntact Ra	tings / Pi	oduct Sp	ecification	ons						
Test Parameters		Test Conditions					Min	Nom	Max	Units		
witching Voltage		DC/Peak AC resistance							100	V		
witching Current	DC/Pea	DC/Peak AC resistance							0.5	Α		
Carry Current DC/Peak AC resist				@30℃)					1.0	Α		
Contact Rating DC/Peak AC resistance								10	W			
Life Expectancy at 1V 10mA							300			x10 <sup>6</sup> Cycle		
contact Resistance		Max Initial Operete Voltage							150	mΩ		
contact Resistance Stability	Max Init	Max Initial Operete Voltage							5	mΩ		
sulation Resistance		Between Contacts					10 <sup>11</sup>			Ω		
Contacts			ntacts to Shield				10 <sup>11</sup>			Ω		
Contacts to Coil						10 <sup>11</sup>			Ω			
	Shield to	Shield to Coil					10 <sup>11</sup>			Ω		
	(at 100	(at 100V 20°C 65%)										
ielectric Strength	Between	Between Contacts					200			VDC		
Static)	Contact	Contacts to Shield					250			VDC		
	Contact	Contacts to Coil					250			VDC		
		Shield to Coil					250			VDC		
Operate Time at Nominal Coil Voltage									0.5	msec		
ncluding Bounce)	Bounce) 100Hz Square Wave											
Release Time Diode Suppression									0.5	msec		
Measurement Reference Condition				Environmental Ratings								
Temp : 15°C to 35°C				Operate temp : -20°C to +60°C								
lumidity : 25% to 75%RH				Storage temp : -40°C to +85°C								
tmospheric Pressure :	860 to 106	60 to 1060hpa Vibration : 20G's to 2000Hz						lz				
			Shock : 50G's									
		Processing Temp : 260°C max for 60sec. dwell time.										

<sup>★</sup> See p 37, 38 for S-parameters and eye diagram.

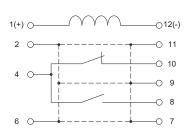
<sup>★</sup> For reel packaged version, see p 43.

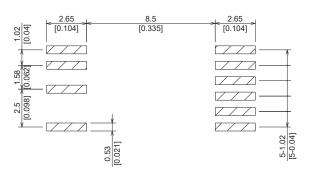
### Dimensions < All Dimensions are mm(inch) >

\* Pin mark ( • ) corresponds to the terminal number 1.



### Schematic <Top View>





<sup>\*</sup> Coil polarities, (+) and (-).

# MJ 2A2B J-Lead: Compact SMT Relay



This product was developed for use in differential circuits for semiconductor automatic testers and semiconductor inspection boards. This product consists of two transfer switches (1A+1B) in one package. As a result, compared to using two of our MGT/MJT relays, this relay reduces mount area by 25%. In addition, the electrical life is guaranteed to 300 million cycles (equivalent to a make switch) and it also supports frequencies from DC to 4.0GHz.

#### Characteristics

- Mount area: 10.3mm x 11.3mm

- Electrical lifespan: 300 million (@ 1V 10mA)

- Insulation resistance:  $>10^{11}\Omega$ 

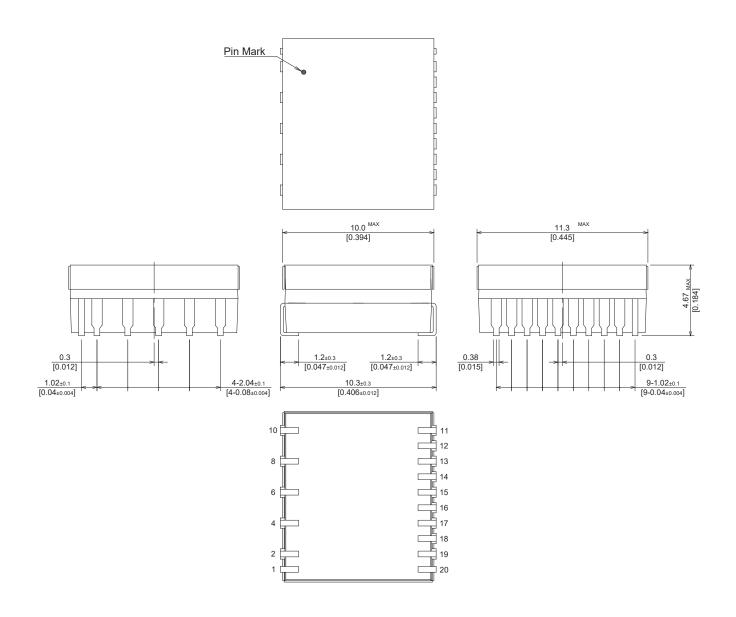
- Frequencies: DC to 4.5GHz (insertion loss: -3dB typ)

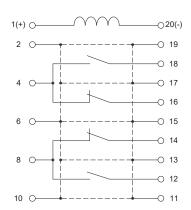


MJ 1A1B Series		MJ-E2T05N				MJ-E2T12N					
Contact Con	2 Form C (A + B)							-			
00.110.01	ga.a	1	Coil Sp	ecifications	0 (1112)						
Parameters	Conditions	Min	Nom	Max	Min	Non	m Max		Units		
Coil Voltage	1	1	5.0	5.5		12.0	12.0 13.2		VDC		
Coil Resistance	±10% @20°C		110			550			Ω		
Must Operate	@20℃			3.75		8.8		8.8	VDC		
Must Release	@20℃	0.7			1.2				VDC		
	•	Contac	t Ratings /	Product Speci	fications				•		
Test Para	meters		Min	Nom	Max	Units					
Switching Voltage			DC/Peak AC resistance					100	V		
Switching Current		DC/Peak A0	DC/Peak AC resistance					0.5	Α		
Carry Current DC/Peak AC resista				e(@30°C)				1.0	Α		
Contact Rating DC/Peak AC resistance								10	W		
Life Expectancy at 1V 10mA						300			x10 <sup>6</sup> Cycle		
Contact Resistance Max Initial Operete				age				180	mΩ		
Contact Resistance Stability Max Initial Operete				age				5	mΩ		
Insulation Resistance Between Contacts Contacts to Shield Contacts to Coil			ntacts			10 <sup>11</sup>			Ω		
			Contacts to Shield						Ω		
			Coil			10 <sup>11</sup>			Ω		
Shield to Coil						10 <sup>11</sup>			Ω		
(at 100)			at 100V 20°C 65%)								
Dielectric Strength Between			etween Contacts						VDC		
(Static)	Contacts to	250			VDC						
	Contacts to	Contacts to Coil						VDC			
	Shield to Co	250			VDC						
Operate Time at Nominal Coil Voltage								0.3	msec		
(Including Bounce) 100Hz Square Way											
Release Time Diode Suppression								0.3	msec		
Measurement Reference Condition				Environmental Ratings							
Temp : 15°C to 35°C			0	Operate temp : -20°C to +60°C							
Humidity	: 2	25% to 75%RI	H S	Storage temp : -40°C to +85°C							
Atmospheric Pressu					to 2000Hz						
				Shock : 50G's							
		Processing Temp : 260°C max for 60sec. dwell time.									

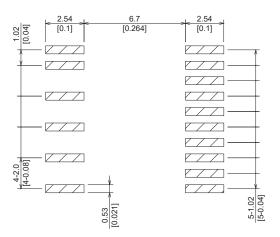
<sup>★</sup> See p 39-42 for S-parameters and eye diagram.

<sup>★</sup> For reel packaged version, see p 43.

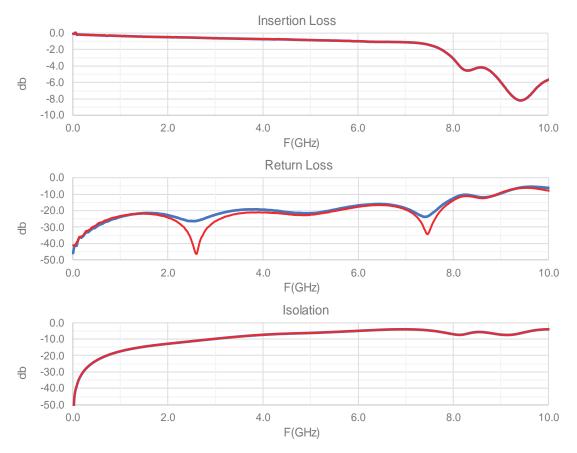




\* Coil polarities, (+) and (-).



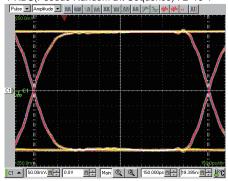
### UJ-1xxRF S-Parameters





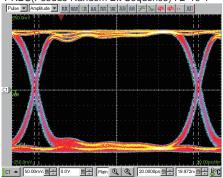
Thru\_Fixture

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



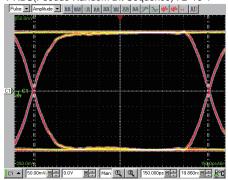
Thru\_Fixture

Rise Time = 30ps Bit Rate : 6.4Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



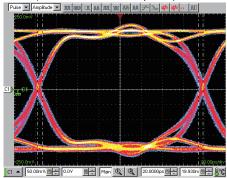
UJ-105RF with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

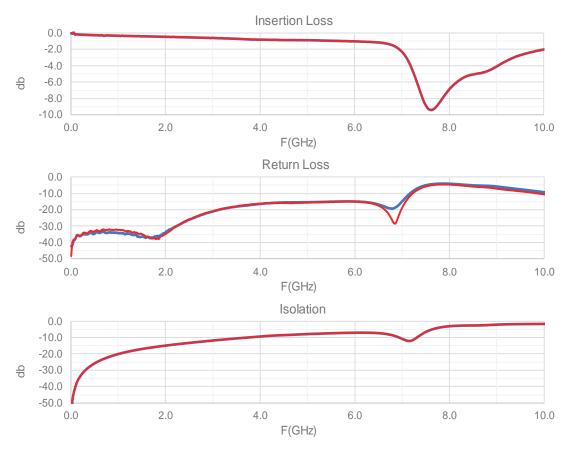


UJ-105RF with Fixture

Rise Time = 30ps Bit Rate : 6.4Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



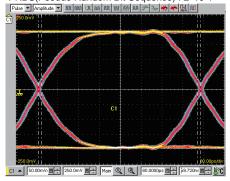
### CJ-1xxRF S-Parameters



Eye Diagram

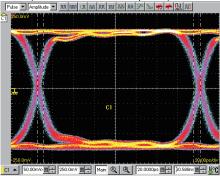
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



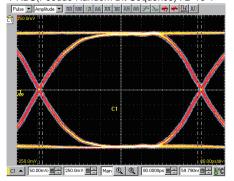
Thru\_Fixture

Rise Time ≒ 30ps Bit Rate : 6.4Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



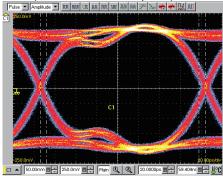
CJ-E105RF with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

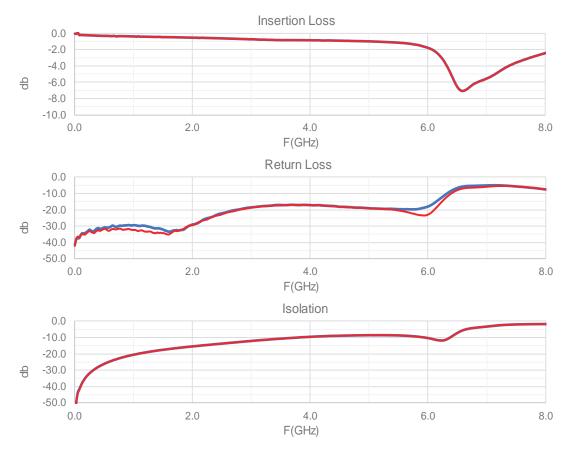


CJ-E105RF with Fixture

Rise Time ≒ 30ps Bit Rate : 6.4Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



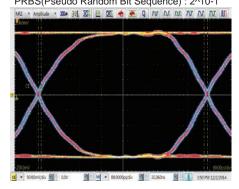
### MG-E105H-64 S-Parameters



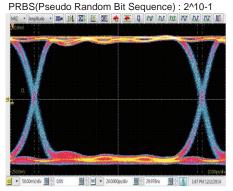
Eye Diagram

Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

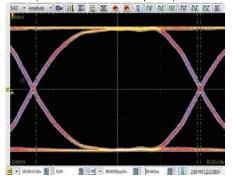


Thru\_Fixture
Rise Time = 250ps Bit Rate : 1.6Gb/s



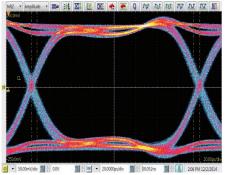
MG-E105H-64 with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

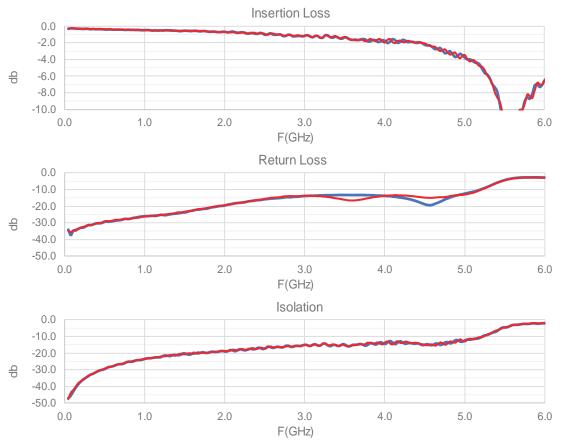


MG-E105H-64 with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



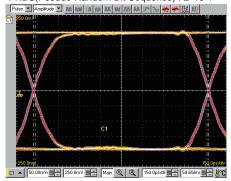
CJ-1xx S-Parameters





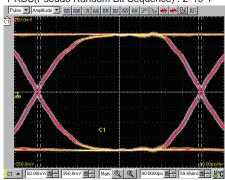
Thru\_Fixture

Rise Time = 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



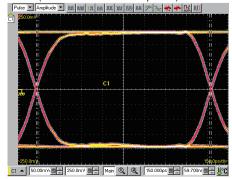
Thru\_Fixture

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



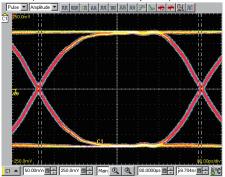
CJ-E105 with Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

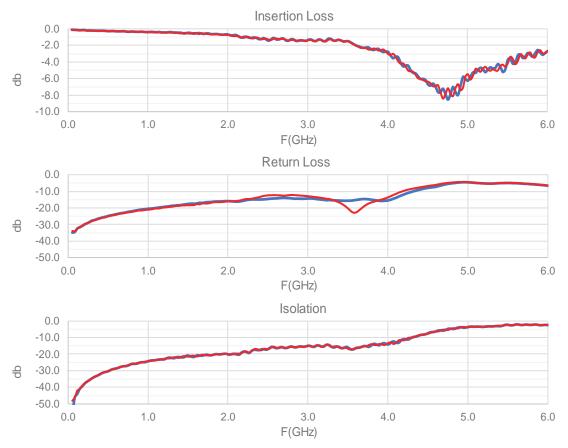


CJ-E105 with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



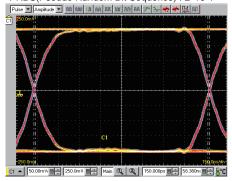
### MG/MJ-E1xx S-Parameters



Eye Diagram

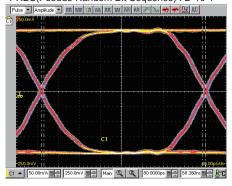
Thru\_Fixture

Rise Time = 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



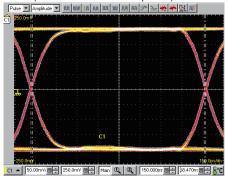
Thru\_Fixture

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



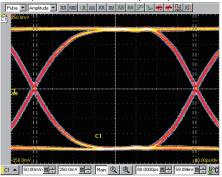
### MJ-E105 with Fixture

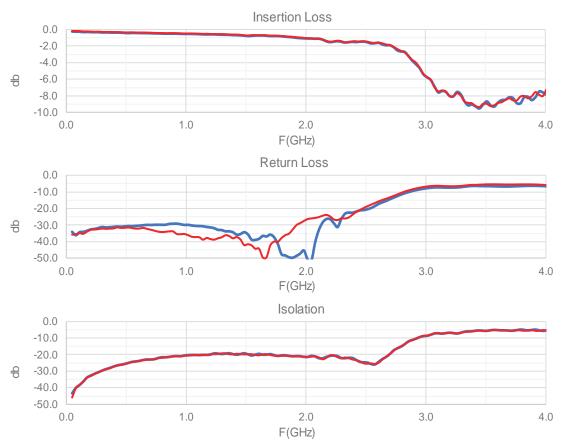
Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



### MJ-E105 with Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

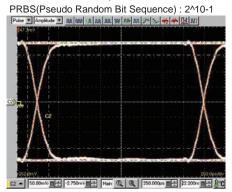






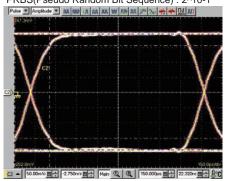
Thru\_Fixture

Rise Time  $\doteq$  250ps Bit Rate : 500Mb/s



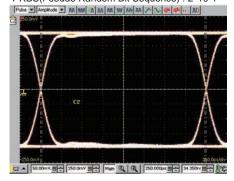
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



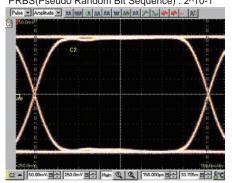
MSG-105AK3H with Fixture

Rise Time ≒ 250ps Bit Rate : 500Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

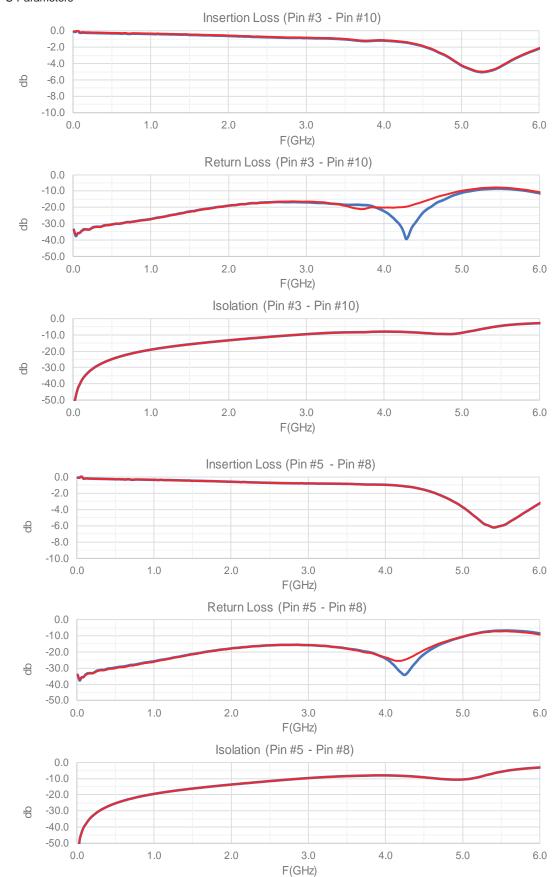


MSG-105AK3H with Fixture

Rise Time = 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



### MG/MJ-E2xxAH S-Parameters

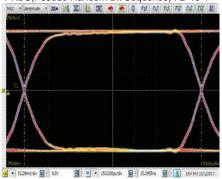


#### MG/MJ-E2xxAH

# Eye Diagram

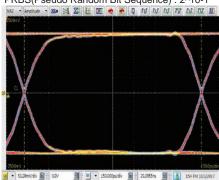
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



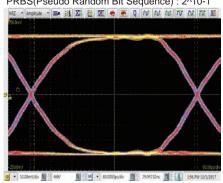
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



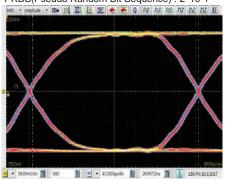
Thru\_Fixture

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

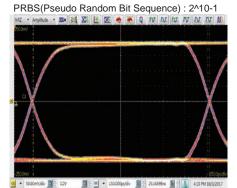


Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

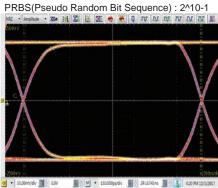


MG-E205AH with Fixture : Pin #3 - Pin #10 Rise Time  $\stackrel{\Leftarrow}{=}$  250ps Bit Rate : 800Mb/s



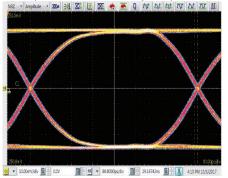
MG-E205AH with Fixture : Pin #5 - Pin #8

Rise Time = 250ps Bit Rate: 800Mb/s



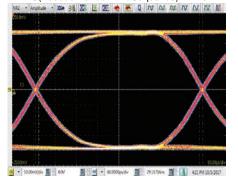
MG-E205AH with Fixture : Pin #3 - Pin #10

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

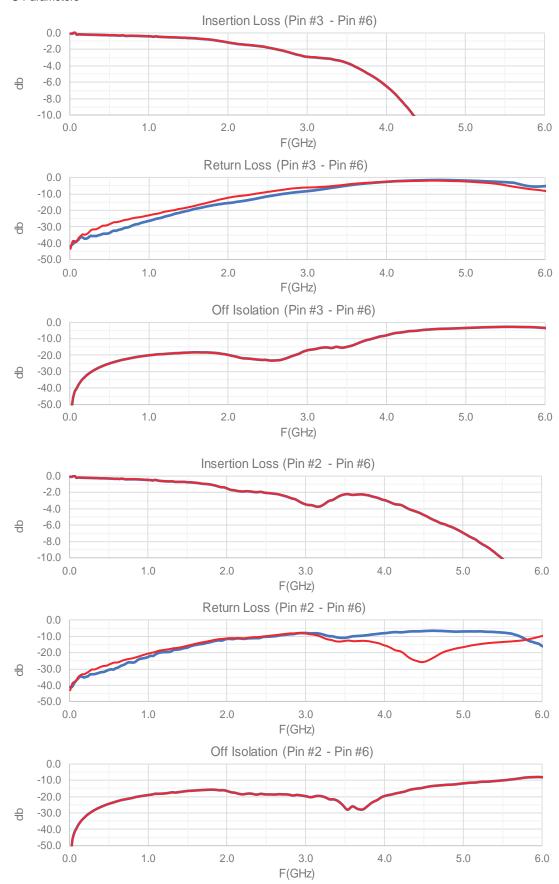


MG-E205AH with Fixture : Pin #5 - Pin #8

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



# MH-E1TxxJH S-Parameters

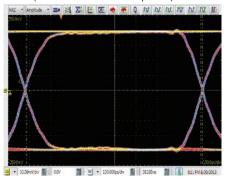


#### MH-E1TxxJH

# Eye Diagram

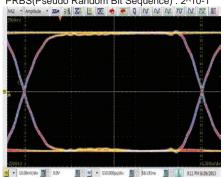
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



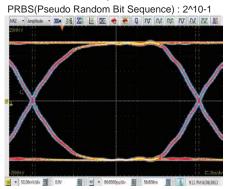
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



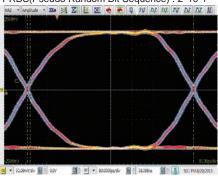
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s

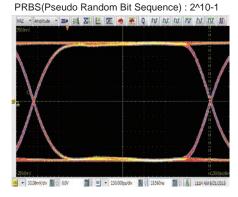


Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

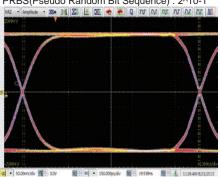


MH-E1T05JH with Fixture : Pin #2 - Pin #6
Rise Time = 250ps Bit Rate : 800Mb/s



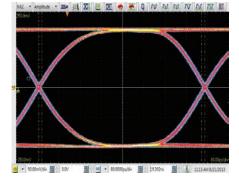
MH-E1T05JH with Fixture : Pin #3 - Pin #6

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



MH-E1T05JH with Fixture : Pin #2 - Pin #6

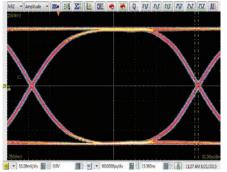
Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



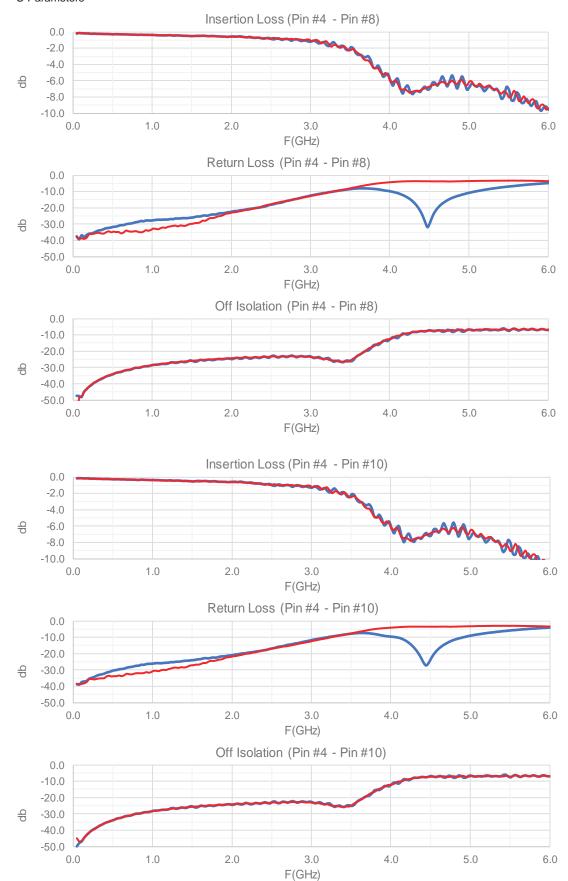
MH-E1T05JH with Fixture : Pin #3 - Pin #6

Rise Time 

⇒ 250ps Bit Rate : 1.6Gb/s
PRBS(Pseudo Random Bit Sequence) : 2^10-1



# MGT/MJT-E1xxH S-Parameters

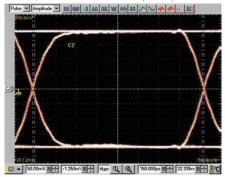


#### MGT/MJT-E1xxH

Eye Diagram

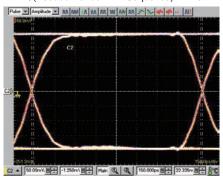
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



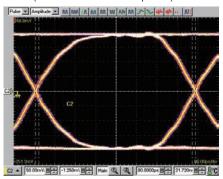
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1

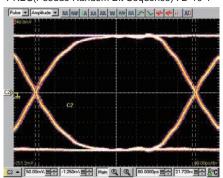


Thru\_Fixture

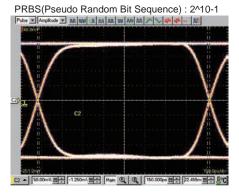
Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



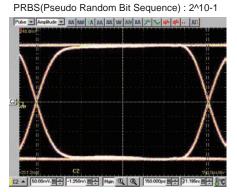
Thru\_Fixture



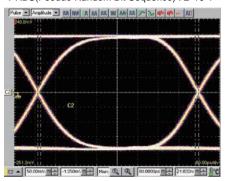
 $\begin{tabular}{lll} MGT-E105H & with Fixture: Pin \#4 - Pin \#8 \\ Rise Time & = & 250ps & Bit Rate: 800Mb/s \\ \end{tabular}$ 



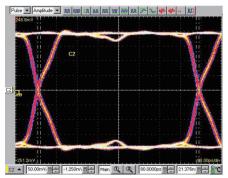
MGT-E105H with Fixture : Pin #4 - Pin #10 Rise Time = 250ps Bit Rate : 800Mb/s



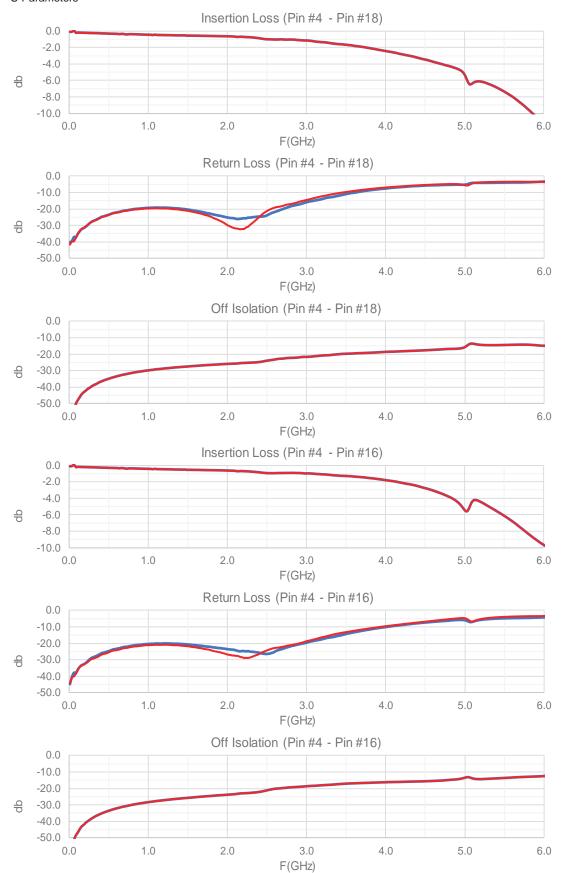
$$\begin{split} & \text{MGT-E105H with Fixture : Pin \#4 - Pin \#8} \\ & \text{Rise Time} \quad \doteq \quad 250 \text{ps} \quad \text{Bit Rate : 1.6Gb/s} \\ & \text{PRBS(Pseudo Random Bit Sequence) : 2^10-1} \end{split}$$



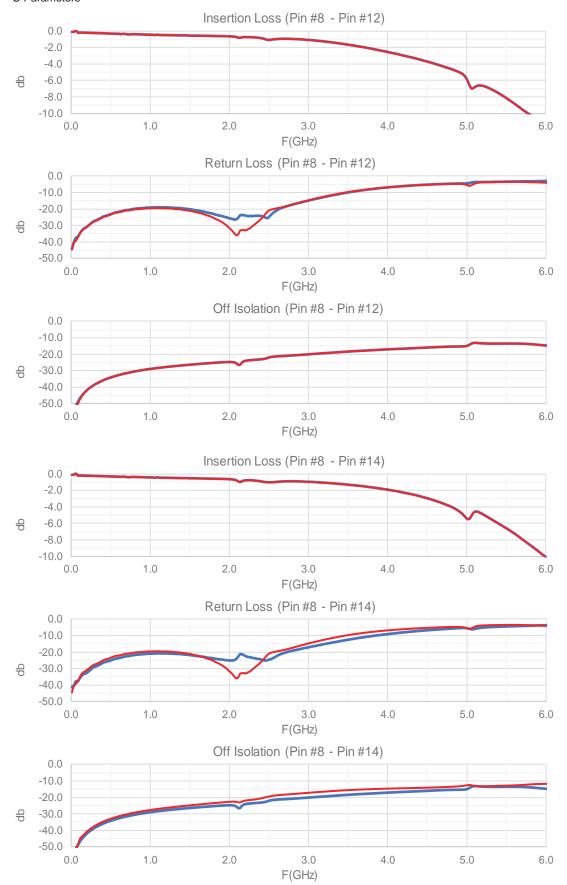
MGT-E105H with Fixture : Pin #4 - Pin #10
Rise Time = 250ps Bit Rate : 1.6Gb/s
PRBS(Pseudo Random Bit Sequence) : 2^10-1



MJ-E2TxxN S-Parameters



# MJ-E2TxxN S-Parameters

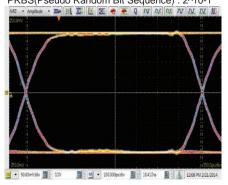


#### MJ-E2TxxN

# Eye Diagram

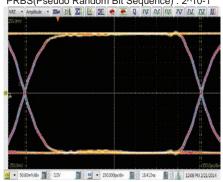
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



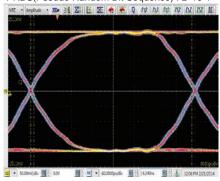
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



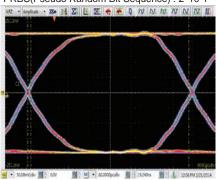
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

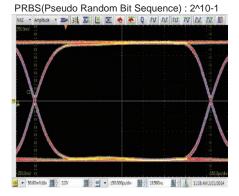


Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



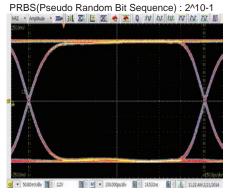
MJ-E2T05N with Fixture : Pin #4 - Pin #18
Rise Time = 250ps Bit Rate : 800Mb/s



MJ-E2T05N with Fixture: Pin #4 - Pin #16

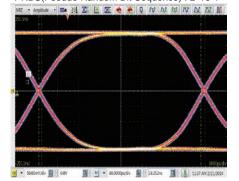
Rise Time 

⇒ 250ps Bit Rate : 800Mb/s



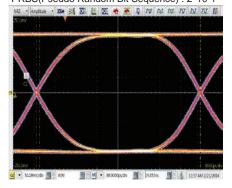
MJ-E2T05N with Fixture : Pin #4 - Pin #18

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



MJ-E2T05N with Fixture : Pin #4 - Pin #16

Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

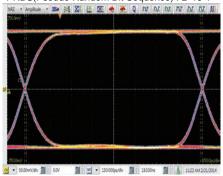


#### MJ-E2TxxN

# Eye Diagram

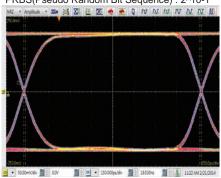
Thru\_Fixture

Rise Time ≒ 250ps Bit Rate : 800Mb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



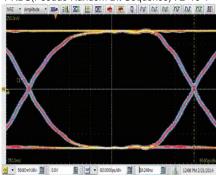
Thru\_Fixture

Rise Time = 250ps Bit Rate: 800Mb/s PRBS(Pseudo Random Bit Sequence): 2^10-1



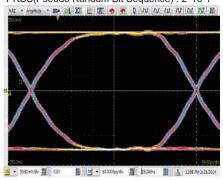
Thru\_Fixture

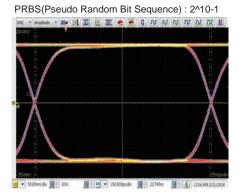
Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



Thru\_Fixture

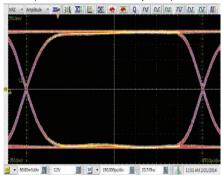
Rise Time ≒ 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1





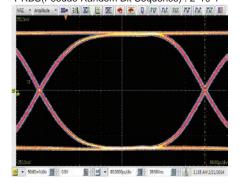
MJ-E2T05N with Fixture : Pin #8 - Pin #14
Rise Time = 250ps Bit Rate : 800Mb/s

PRBS(Pseudo Random Bit Sequence) : 2^10-1



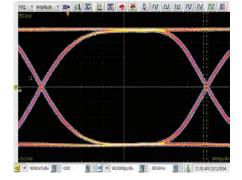
MJ-E2T05N with Fixture : Pin #8 - Pin #12

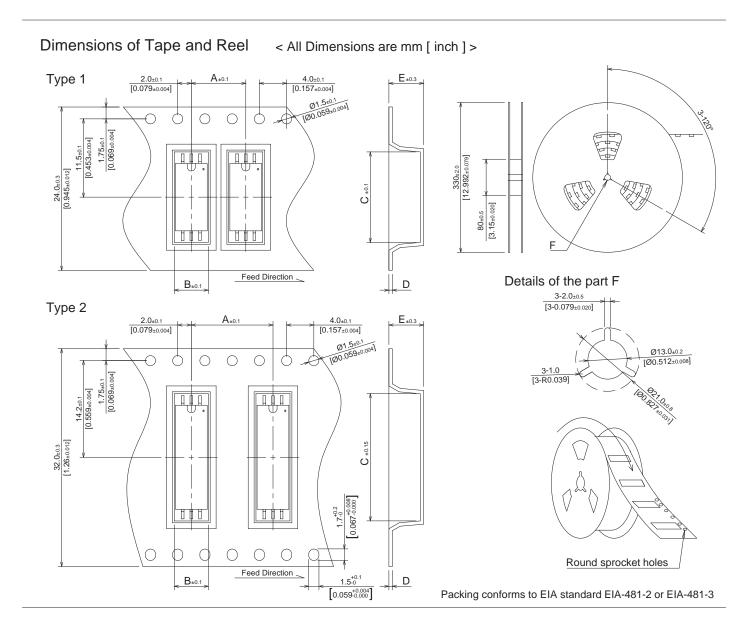
Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1



MJ-E2T05N with Fixture : Pin #8 - Pin #14

Rise Time = 250ps Bit Rate : 1.6Gb/s PRBS(Pseudo Random Bit Sequence) : 2^10-1

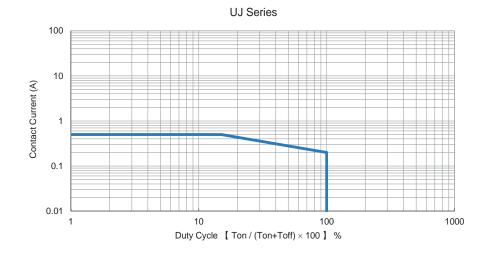


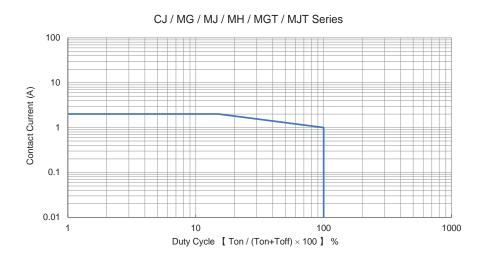


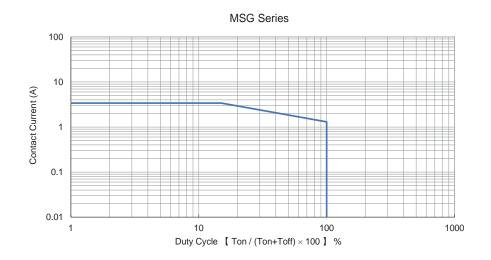
# Dimensions value detail and Packing Quantity

Madal Name	T	А		В		С		D		E		CDO
Model Name	Туре	mm	inch	mm	inch	mm	inch	mm	inch	mm	inch	SPQ
UJ-1xxRF	1	8.0	0.315	4.9	0.193	8.5	0.335	0.5	0.020	4.4	0.173	2,000
CJ-E1xxRF	1	12.0	0.472	4.9	0.193	9.4	0.370	0.4	0.016	4.3	0.169	1,000
MG-E105H-64	1	12.0	0.472	5.0	0.197	13.3	0.524	0.5	0.020	5.1	0.201	1,000
CJ-E1xx	1	8.0	0.315	4.0	0.157	9.5	0.374	0.5	0.020	4.4	0.173	2,000
MG-E1xx	1	12.0	0.472	5.0	0.197	13.3	0.524	0.5	0.020	5.1	0.201	1,000
MJ-E1xx	1	12.0	0.472	4.9	0.193	11.0	0.433	0.4	0.016	5.5	0.217	1,000
MSG-1xxAK3H	2	12.0	0.472	4.9	0.193	20.8	0.819	0.5	0.020	5.4	0.213	1,000
MG-E2xxAH	1	12.0	0.472	7.0	0.276	13.2	0.520	0.5	0.020	5.7	0.224	500
MJ-E2xxAH	1	12.0	0.472	6.8	0.268	10.4	0.409	0.5	0.020	6.0	0.236	500
MH-E1TxxJH	1	12.0	0.472	5.4	0.213	10.75	0.423	0.5	0.020	9.0	0.354	500
MGT-E1xxH	1	12.0	0.472	8.0	0.315	13.1	0.516	0.5	0.020	5.7	0.224	500
MJT-E1xxH	1	12.0	0.472	8.3	0.327	11.0	0.433	0.5	0.020	5.9	0.232	500
MJ-E2TxxN	1	16.0	0.630	11.6	0.457	10.6	0.417	0.5	0.020	5.5	0.217	500

# Pulse current reduction curve





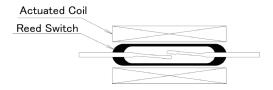


# **Overview of Reed Relays**

# 1) What are reed relays

A reed relay is based around a reed switch. A reed switch contains two ferromagnetic reeds sealed inside a glass tube facing each other with a small gap between them. The glass tube is filled with an inert gas to prevent the contacts from being activated, and the contacts are plated with a special metal.

The relay opens and closes the contacts by moving the switch reeds with the magnetic force generated from a coil wound around the glass tube of the switch.



# 2) Comparison of reed relays and other relays

ltem	R e e d R e I a y	Mechanical Relay	Mechanical Relay	S S R	O p t i c a l M O S
Appearance	0	0	Δ	0	0
Number of contact poles	0	0	0	Δ	Δ
Power consumption	0	0	Δ	0	0
Response speed	0	Δ	Δ	0	0
Contact reliability	0	Δ	Δ	0	0
Bounce	0	Δ	Δ	0	0
Insulation	0	0	0	Δ	0
Durability	0	0	Δ	0	0
Transient response	0	0	0	Δ	Δ
Operation noise	0	Δ	Δ	0	0
Operation noise					
Vibration and shock resistance	Δ	Δ	Δ	0	0
	-	Δ	Δ	© 0	© ©
Vibration and shock resistance	Δ				
Vibration and shock resistance Surrounding environment	Δ	Δ	Δ	0	0

# 3) Terminology

	Terms		Explanation						
			Non-operating state	Operating state					
		Form A (1 make)	·	oto					
	1 Contact types	Form B (1 break)	·	·					
1		Form C (transfer)		0					
		Form C (A+B) (make-break)							
		Form (A+B) (make-break)	0 + 0	0 t 0					
2	Rated voltage	This is the specified voltage that is applied to the coil to operate the relay.  The allowable fluctuation of the rated voltage is within ±10% (at 20°C).							
3	Coil resistance	The coil resistance of the relay is expressed in $\Omega$ .							
4	Operate voltage	This is the minimum coil voltage required to operate the relay.  For example, if a voltage of 3.3V is applied to a relay with an operating voltage of 3.75V, it will not operate.							
5	Release voltage	This is the coil voltage required to return an activated relay to a deactivated state.  For example, if a voltage of 0.5V is applied to a relay with a release voltage of 1.2V, it will assume a deactivated state.  If a voltage of 1.5V is applied, it will not assume a deactivated state.							
6	Maximum switching voltage	This is the max voltage (at 1mA) that can open/close the contacts when a load is connected. ("peak voltage value" for AC)  However, please use within the maximum contact capacity (see 9. below).  Using a voltage that exceeds the maximum switching voltage may cause the contacts to melt or accelerate deterioration.							
7	Maximum switching current	This is the max current that can open/close the contacts when a load is connected to the contacts. ("peak current value" for AC)  However, please use within the maximum contact capacity (see 9. below).  Using a current that exceeds the maximum switching current may cause the contacts to melt or accelerate deterioration.							
8	Maximum carry current	This is the maximum current that can flow continuously after the contacts are closed.  When opening the contacts, do so at a current value less than the maximum switching current.							
9	Maximum contact capacity	This is the maximum load capacity (switching voltage x switching current) that can be switched without practical problems.  Using a capacity value that exceeds the maximum contact capacity may cause the contacts to melt or accelerate deterioration.							
10	Electrical lifespan	This is the lifespan when a load is applied to the contacts.  The lifespan of a relay varies depending on the size and type of load, and frequency of use.							
11	Contact resistance (initial value)	This is the resistance between the terminals when the contacts are closed.							
12	Contact resistance variation (initial value)	The contact resistance is measured 5 times and a range between the min and max values is set to ensure stability of the value.							
13	Insulation resistance	This is the resistance of the insulated parts between contacts/coils/conductive terminals and non-conductive terminals (such as an iron core frame or iron core), or between contacts themselves.							
14	Electrostatic capacitance	This is the capacitance b	etween contacts, coils, and conductive terminals.						
15	Breakdown voltage	This is the limit value at which insulation breakdown does not occur between each conductor of the relay.  This is the voltage that can be withstood even if a surge is applied between the contacts when the contacts are not operating.							
16	Operate time	For a voltage pulse applied immediately after the contacts operate, the maximum switching voltage is the standard value.  This is the time from when the rated voltage is applied to the coil until the contacts operate.  (Including bounce. Form A/Form C/FORM (A+B))							
17	Release time	This is the time it takes for the contacts to reset after the rated voltage is removed from the coil.  (Including bounce. Form B/Form C/FORM (A+B))							
18	Vibration	This is the vibration resistance value that does not cause changes in properties.							
19	Shock	This is the shock resistance value that does not cause changes in properties.							

# 4) Precautions for use

# 4-1) Adding a surge absorbing diode

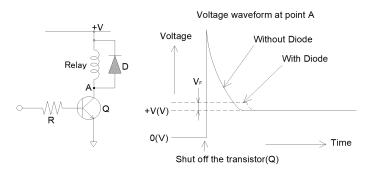
When driving a coil, please add a clamp diode in parallel to the coil as shown in the diagram on the right.



#### 4-2) Back electromotive force (EMF) of the coil

This is the voltage that occurs in an inductive circuit when the current changes and the polarity of the induced voltage at each instant is opposite to the polarity of the applied voltage. This phenomenon does not occur during direct current flow where the current does not change; however, care must be taken as back EMF occurs when the current begins to flow or is cut off.

The voltage waveform at point A in the diagram can be as much as 10 times the applied voltage, and when a reed relay (coil) on/off is controlled by a transistor, this can exceed the transistor's withstand voltage (V CE) and destroy the transistor. For this reason, a protection circuit of a diode in parallel with the reed relay (coil) is effective in absorbing the back EMF.

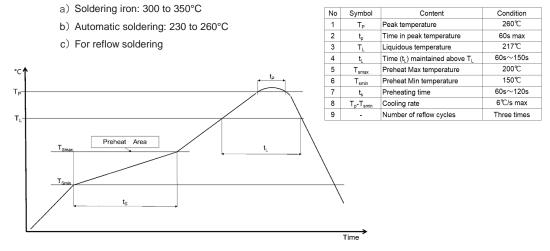


\* If a diode is installed, the release time will be slower due to the influence of VF (diode forward voltage).

#### 4-3) Terminal bending

When bending the relay terminals for installation, hold the terminals in place with lead pliers before bending them. When bending, be careful not to put undue stress on the base of the terminal.

# 4-4) Soldering conditions



# 4-5) Cleaning

If, after soldering the relay, the board is washed with a solvent (alcohol-based, freon-based) or pure water to remove flux, please note the following:

- a) Cleaning with solvents may cause markings to fade, chip, or disappear.
- b) Avoid ultrasonic cleaning
- c) Do not perform cleaning in a bath with a large magnetic field as this will change the properties of the relay.
  - \* Please contact us regarding whether cleaning is possible.

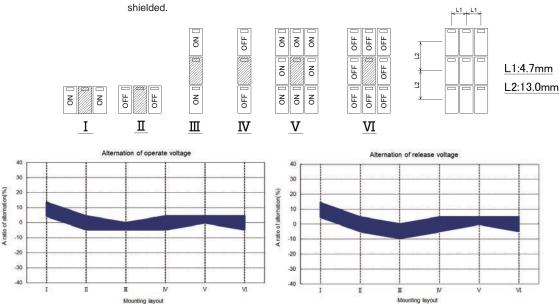
# 4-6) Magnetic interference

When multiple reed relays are mounted close together, mutual magnetic interference occurs, causing operating and release voltage fluctuations. The diagrams below illustrate how different configurations of surrounding reed relays can magnetically interfere with the reed relay in the center. This value changes depending on whether or not electricity is applied.

The graphs shows the variations in operation of the central reed relay.

A magnetic shield is an effective way to suppress these fluctuations.

Note: Using a relay in an environment where a strong magnetic field is generated by an external transformer or permanent magnet may cause the relay to malfunction even if it is magnetically



#### 4-7) Mechanical shock

The properties of the relay may change if it is subjected to mechanical shock, such as being dropped

## 4-8) Contact protection

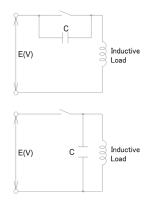
The use of contact protection elements and protection circuits can keep back EMF low, but note that using them incorrectly can have the opposite effect.

The table below shows some typical examples of contact protection circuits.

#### a) Inductive load

Item	Oleverth Francisco	Applications		Para anti-	Commonant colection		
Category	Circuit Example	AC DC		Properties, etc.	Component selection		
CR Method	R C Inductive Lead	• A O		When used with AC voltage, the load impedance must be significantly smaller than the CR impedance. When the contacts are open, current flows through the capacitor and resistor to the inductive load.	in relay characteristics.  Please confirm this through experiments, keeping in mind that the		
	E(V) R Dinductive Load	0	0	If the load is a relay or solenoid, the release time will be delayed. When the power supply voltage is 24 or 48V, it is better to connect between the loads. When it is 100 to 200V, connecting between the contacts is better.	capacitor is responsible for the discharge control effect when the contacts are opened, and the resistor is responsible for limiting the current when the switch is next turned on. Generally, the withstand voltage of the capacitor should be 200 to 300V. For AC circuits, use AC capacitors (no polarity).		
Diode Method	E(V) Industive		0	The energy stored in the inductive load is passed in the form of current to the coil via a parallel diode, and is dissipated as Joule heat by the resistance of the inductive load.	Use a diode with a reverse withstand voltage of 10 times or more than the circuit voltage and a forward current equal to or greater than the inductive load current. In electronic circuits, if the circuit voltage is not very high, capacitors with a reverse withstand voltage of about 2 to 3 times the power supply voltage can be used.		
Diode + Zener Diode Method	E(V) S Inductive	0	0	Effective when the release time is too slow with the diode method.	The Zener voltage of the Zener diode should be approximately the same as the power supply voltage.		
Varistor Method	E(V) S Inductive	0	0	This method uses the constant voltage characteristics of the varistor to prevent too high a voltage from being applied across the contacts. When the power supply voltage is 24 to 48V, it is better to connect between the loads. When it is 100 to 200V, connecting between the contacts is better.			

Avoid using circuits like those shown below.



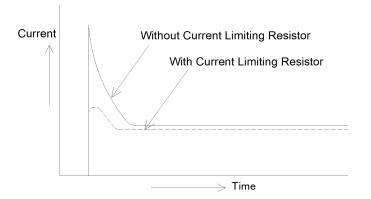
Very effective in extinguishing the arc when cut off, but because capacitance is stored in C when the contacts are opened, a short-circuit current flows in C when the contacts are closed, making them susceptible to becoming fused together.

Very effective in extinguishing the arc when cut off,but a charging current flows in C when the contacts are closed making them susceptible to becoming fused together.

### b) Lamp load (inrush current), etc

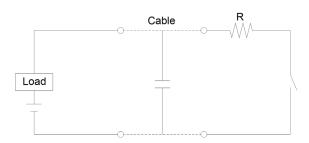
When the contact load is a lamp, motor, solenoid, capacitor, etc., an inrush current several times to several dozen times the steady-state current flows when the contact is closed. If this inrush current exceeds the allowable range, it can cause contact failure due to contact fusion or transfer of contact metal. The allowable inrush current of a reed relay is determined by factors such as the magnitude of the inrush current, its waveform, and the number of cycles required of the reed relay contacts.

Inserting a current-limiting resistor in series with the contacts is an effective way to suppress the inrush current below the maximum switching current. Please refer to the diagram to check whether the product can be used under the actual conditions.



# c) Line-to-line stray capacitance

Inrush current that occurs when line-to-line stray capacitance is large can be a problem. As shown in the figure, the charge stored in the stray capacitance between the lines is discharged when the contacts are closed. The smaller the impedance of the wiring cable and the longer the cable, the greater the contact wear. Please insert a current-limiting resistor in series with the contact as a protection circuit to suppress the inrush current.



#### 4-9) Thermoelectromotive force

When dissimilar metals are connected and the junction is kept at different temperatures, a current flows through the circuit due to the Seebeck effect. The electromotive force that generates this current is called thermoelectromotive force. For reed relays, thermal electromotive forces are generated between the dissimilar metals of the terminals, contact pieces, and contact points.

When a thermocouple is switched using a reed relay, this thermoelectromotive force can cause a difference between the measured temperature and actual temperature.

#### Seebeck effect:

A phenomenon when different metals A and B are bonded in a ring to create a closed circuit. The two junctions are kept at different temperatures, generating an electromotive force at the junctions and causing an electric current to flow. This is the opposite of the Peltier effect. If the temperature is reversed, the electromotive force (current) will also be reversed. This phenomenon is the mechanism behind thermocouples because it allows measurement over a relatively wide temperature range.

# 4-10) Dynamic properties of reed relays

When current flows through a reed relay, there is a consistent sequence of events that occur.

These phenomena occur regardless of the type of reed relay.

Details of these contact phenomena are shown in the figure below.

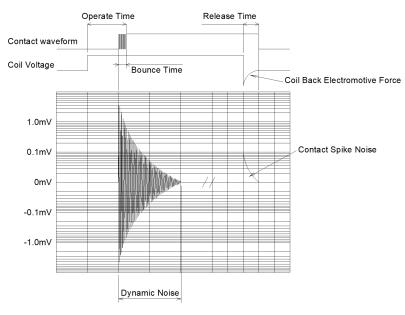


Figure: Overview of dynamic properties

Dynamic noise is a noise component that is generated mainly due to the wavering of the contacts that continues even after the bounce has ended.

# Dynamic Noise

After the contacts close, the energy dissipates with damped oscillation similar to that of a plucked harp string.

During damped vibration, some areas on the contacts are stressed and generate an electrical signal.

This electrical signal is an AC audible signal with a very wide frequency range that oscillates with damped sine waves, with the amplitude and duration of the noise depending on the following conditions.

- Contact spike noise occurs when the contacts try to separate from each other after the applied voltage on the coil is removed.
- Spring strength
- Seal glass properties
- Contact material
- Coil drive power

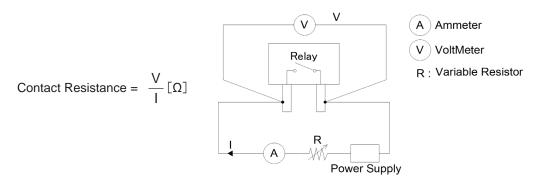
#### 5) Explanation of operation and measurement

#### 5-1) Contact resistance

Contact resistance is the combined value of the inherent resistance of the conductors that make up the circuit, such as the movable parts, terminals, and contacts, and the resistance at the point where the contacts come into contact.

The contact resistance value is an initial value, and the level of this value does not indicate whether the relay will be good or bad in actual use. The contact resistance is measured using the voltage drop method (four terminal method) as shown in the figure, with a measurement current of 1mA.

#### Contact measurement schematic diagram



# 5-2) Operate and release voltage

# a) Operate voltage

This is the minimum voltage required for all contacts to operate when the coil voltage is increased either suddenly or gradually.

## b) Release voltage

This is the voltage at which all contacts return to their original position when the coil voltage is decreased either suddenly or gradually.

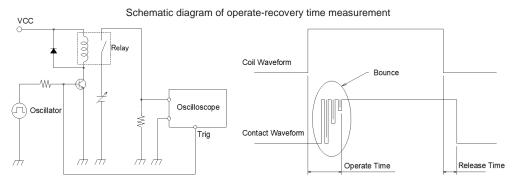
# 5-3) Operate time

The time from when the rated voltage is applied to the coil until the contacts operate.

In the case of a reed relay with multiple contacts, unless otherwise specified, it will be the time it takes for the slowest contact to operate.

# 5-4) Release time

The time it takes for the contacts to return to their original position after the rated voltage is removed from the coil. In the case of a reed relay with multiple contacts, unless otherwise specified, it will be the time it takes for the slowest contact to return to its original position.



# \* What is bounce?

An intermittent switching phenomenon between contacts caused by vibration from the collision of the moving part of a contact with the moving part of the opposing contact or the backstop.

#### 5-5) Capacitance

In a reed relay, capacitance occurs between each conductor.

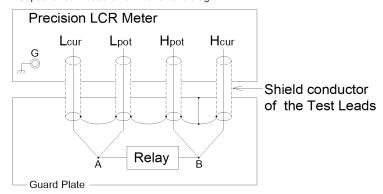
The conditions for measuring capacitance are listed below.

#### a) Measurement conditions

Bias voltage: 1VDC

Measurement frequency: 1MHz

Capacitance measurement schematic diagram



\* When measuring capacitance, the object to be measured is suspended above the shield plate.

#### b) Measurement method

- b-1) Points A and B are positioned based on the distance between the terminals of the relay to be measured.
- b-2) The LCR Meter is calibrated.
- b-3) Points A and B are connected to the relay and capacitance is measured.

  (If an electrostatic shield is attached, the terminal is connected to the GND terminal of the LCR Meter to measure the capacitance.)

## 5-6) Breakdown voltage

This is the limit value at which no dielectric breakdown occurs when voltage is applied for one minute to the insulated parts between contacts, coils, between conductive terminals and non-current-carrying metal parts (such as an iron core frame or iron core), or between contacts.

Testing is done in a dark room with no radiation (light or X-rays) and a leakage current (current for detecting dielectric breakdown) of 1mA.

A distinctive feature of this test is that it is performed using a fast rising waveform when measuring the breakdown voltage.(The voltage waveform during a breakdown voltage test is shown below.)



Exai Example of voltage waveform when 200V is applied

Oscilloscope Settings Voltage range : 50V/1div Frequency range : 1ms/1div

### 5-7) Insulation resistance

This refers to the resistance of the insulated parts between contacts/coils/conductive terminals and non-current-carrying metal parts (such as an iron core frame or iron core), or between contacts themselves.

This value is for the relay alone and does not include the lands on the PCB, etc.

# 5-8) High-frequency properties

At Sanyu, when testing high-frequency properties, we mainly evaluate the following.

TDR(Time Domain Reflectometry)

TDT(Time Domain Transmission)

Isolation

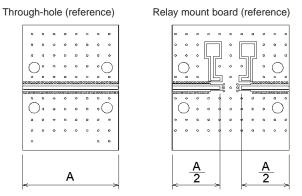
Insertion Loss

Return Loss

#### a) Measurement board

We use the following types of boards for evaluation.

Please note that the wiring on the board may differ depending on the product shape.



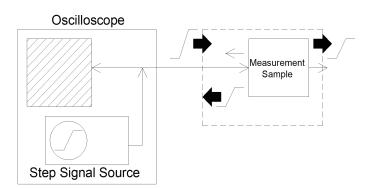
The characteristic impedance of the transmission line is 50  $\Omega$ .

(Board specifications used are an example.)

# b) TDR/TDT

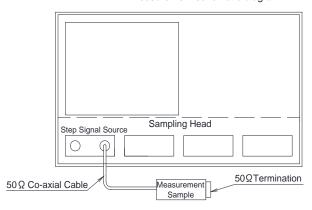
TDR measurements consist of a step signal source and a wideband oscilloscope to capture the reflected signal at the impedance discontinuity in the transmission line and display the voltage and impedance values of the reflected signal as a function of time. Additionally, measurement of the propagated transmission signal is called TDT and is used to measure propagation delay.

Since transmitted signals are distorted by reflections and delays, TDR/TDT provide intuitive measurement results and are essential evaluation criteria.



# b-1) TDR measurement overview

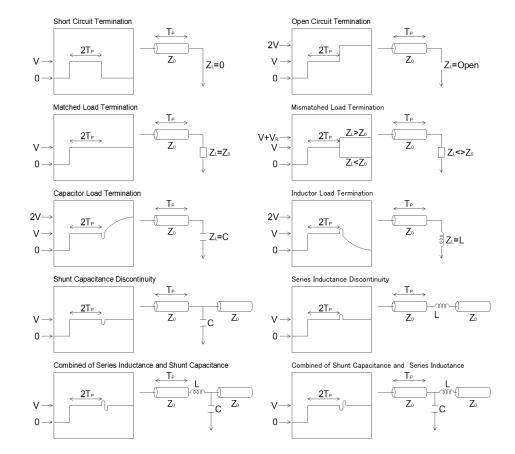
TDR measurement schematic diagram



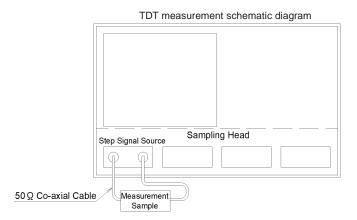
# b-2) Measurement method

When the device under test is connected to the measurement equipment and output is started from the TDR signal source channel, a waveform appears on the wideband oscilloscope screen. The impedance state of the measurement sample can be understood from the waveform.

An example of a TDR measurement waveform is shown below.

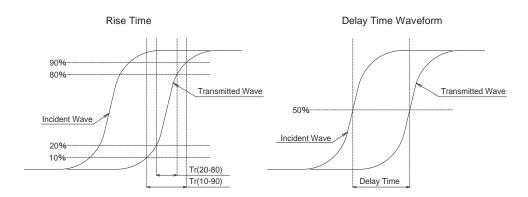


# b-3) TDT measurement overview



# b-4) Measurement method

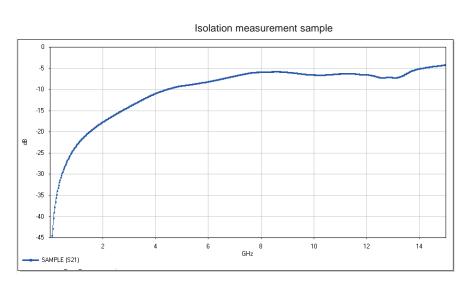
The voltage output from the step signal source is applied to the measurement sample and the transmitted wave is monitored. An example of a TDT measurement waveform is shown below.



# c) Isolation

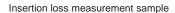
This indicates the degree of insulation for high-frequency signals.

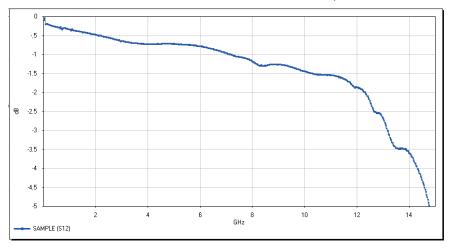
Even when the relay contacts are open,high-frequency signals can leak due to stray capacitance. The insulation that suppresses this leakage is called isolation. An example of an isolation measurement result is shown below.



# d) What is insertion loss?

This refers to the high-frequency signal insertion loss in the transmission line (when the relay is closed). It represents the loss due to impedance mismatch in the circuit of the device under test.



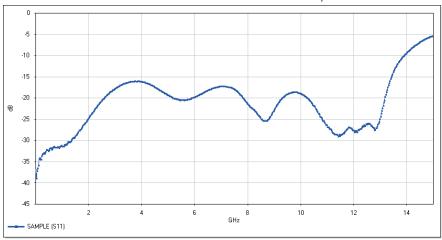


# e) What is return loss?

This refers to the reflection from the device under test (when the relay is closed).

When an incident wave in a transmission line encounters an impedance mismatch, a reflected wave is generated. If the impedance is matched, there will be no reflections.

Return loss measurement sample

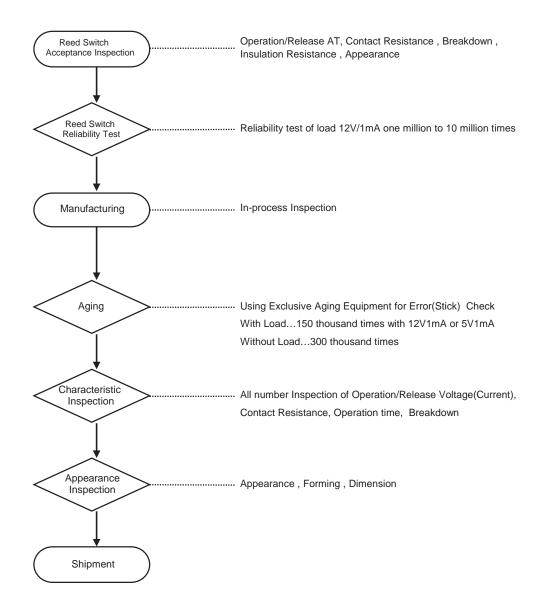


# f) Regarding of high frequency data

We can provide our product high frequency data with De-embeding. Please feel free to ask our sales team.

# 6) Reed and mercury relay quality

Quality control is carried out according to the following flow chart.



# 6-1) Aging (with and without load)

Although the contact points are plated, the surfaces are covered in countless tiny irregularities. If left in this state, the contact resistance will become slightly unstable, so aging is done to smooth and stabilize the contact surface.

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We sincerely thank you, our valued customer, for your continued patronage and use of our products. Unless otherwise agreed upon at the time of purchase of Our Products, the conditions based on these terms of acceptance will apply to the contents listed in the Catalogs, Etc. Please be sure to read and understand these terms of acceptance before using or ordering.

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The terms referred to in this agreement are as follows:

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- 2) Catalogs, Etc.:
  - Refers to comprehensive catalogs, individual catalogs, specifications, manuals, etc. related to Our Products. This also includes what is provided through electronic media.
- 3) Suitability, Etc.:
  - Refers to (a) suitability, (b) operation, (c) non-infringement of third-party intellectual property,(d) compliance with laws and regulations, and (e) compliance with various rules regarding customer use of Our Products.

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